



Le 16/06/2017

# Introduction to High Vacuum in Accelerators

Mercier Bruno LAL

## Introduction to High Vacuum in accelerators.

### Part1: vacuum basis

- 1-1 Kinetic behavior of gas molecules
- 1-2 Mean free path / residence time
- 1-3 outgassing/desorption

### Part2: vacuum in accelerators

- 2-1 interaction residual gas - beam
  - 2-1-a Coulomb scattering
  - 2-1-b Bremsstrahlung
  - 2-1-C Ionization energy loss
  - 2-1-d ion accumulation

### Part3: Technologie evolution

- 3-1 Pressure distribution in accelerators
- 3-2 Distributed pumping
  - 3-2-a getter pump
  - 3-2-b NEG coating

### 2-2 Interaction particules surface

- 2-2-a Synchrotron radiation an Photon stimulated desorption
- 2-2-b Ion stimulated Desorption
- 2-2-c Electron stimulated Desorption an electron-cloud

## Introduction :

### What does vacuum mean?

Vacuum: an absence of matter ?

- Space where the molecules are strongly rarefied compared to atmospheric pressure

$10^{-9}$  mbar  $\sim 25$  millions/cm<sup>3</sup> at 20°C

Pollution source, background noise, parasitic interactions ....

- quantum vacuum:

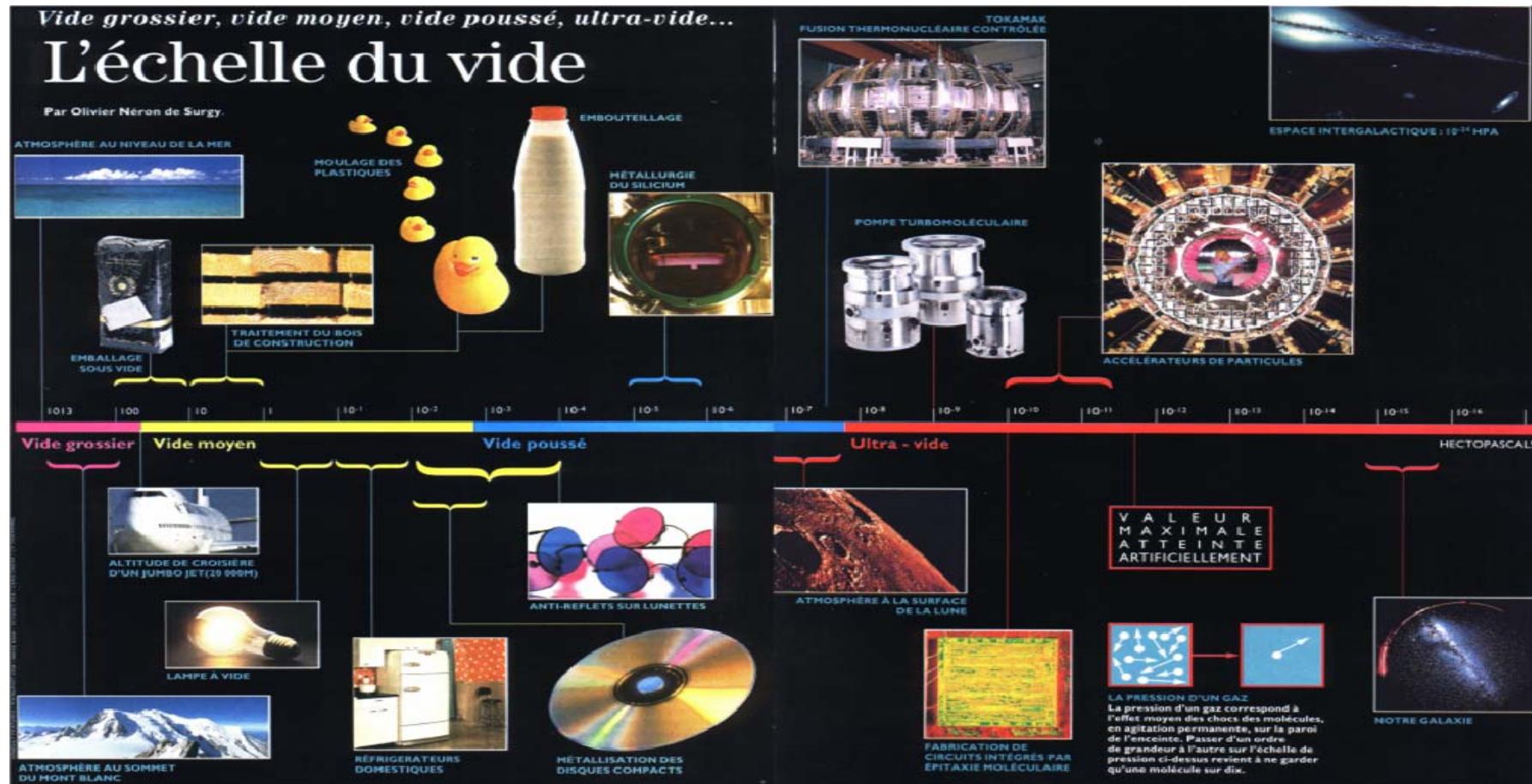
State minimum energy, vacuum fluctuation, ...

a vacuum: full of matter !!

## Introduction :

# The scale

Pressure  $100 \text{ Pa}(\text{N/m}^2) = 1 \text{ mbar} = 0,75 \text{ Torr}$



## Maxwell-Boltzmann velocity distribution

$$\bar{V} = V_m = \sqrt{\frac{8RT}{\pi M}}$$

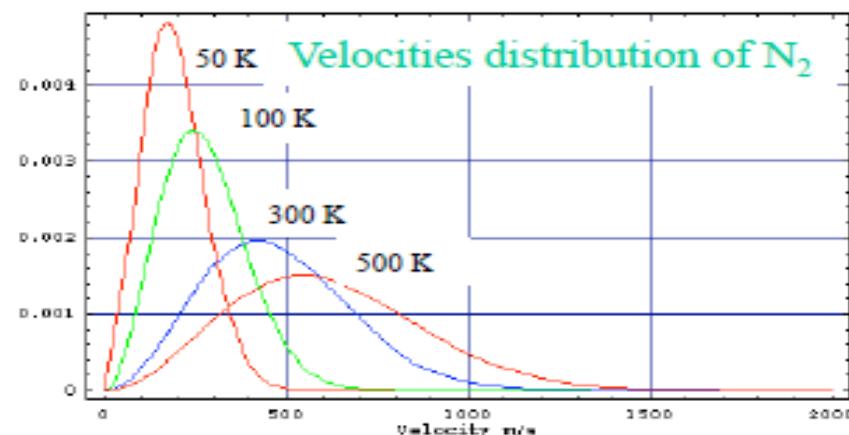
At 20°C

$\text{Ar} \sim 394 \text{ m/s}$

$$V_{\text{rms}} = c = \sqrt{\frac{3RT}{M}}$$

$\text{N}_2 \sim 471 \text{ m/s}$   
 $\text{He} \sim 1246 \text{ m/s}$

Dependent upon composition of gas and temperature



## residence time on the surface

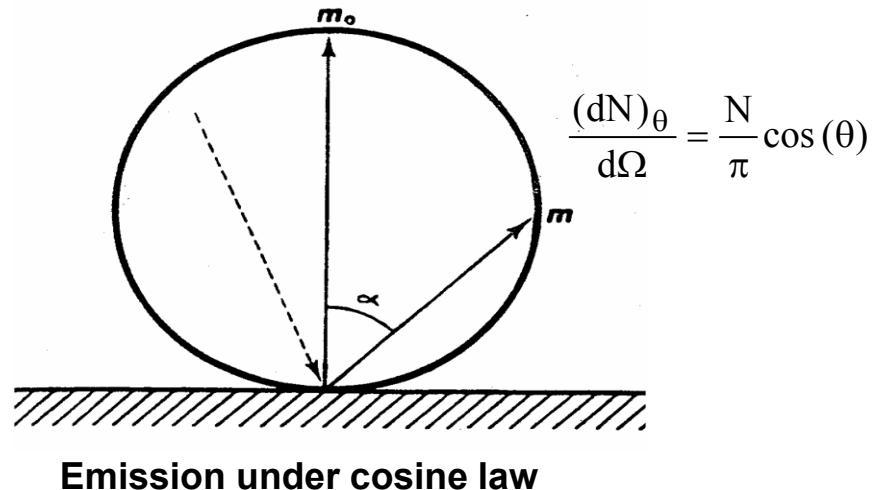
Frenkel formul  
 $\tau_0 \sim 10^{-13} \text{ s}$

$$\tau = \tau_0 \cdot e^{\frac{E}{RT}}$$

E desorption energy

$20 < E < 25 \text{ kcal/mol} \rightarrow 80 \text{ s} < \tau < 5 \text{ days at } 20^\circ \text{C}$

Increase pumping time



## Monolayer formation time

And considering the molecule as spherical, for perfect atomic arrangement:

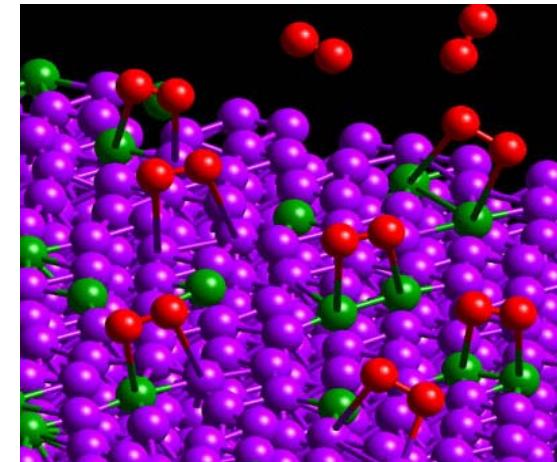
$$\tau = \frac{4}{d^2 \cdot n \cdot v_m}$$

(very approximate)

Order of magnitude one monolayer  $\sim 10^{15}$  molécules/cm<sup>2</sup>

$\tau \sim 40$  min at  $P=10^{-9}$  mbar ( $N_2$ )

$\tau \sim 3$  sec at  $P=10^{-6}$  mbar ( $N_2$ )



The concept of monolayer can appreciate the cleanliness of the surface

## Mean Free Path

It is the path length that a molecules traverse between two succesives impacts with other molecules.

$$l_m = \frac{1}{\sqrt{2\pi} \cdot d^2 \cdot n}$$

$l_m \sim 64$  km at  $P=10^{-9}$  mbar ( $N_2$ )  
 $l_m \sim 6.5$  m at  $P=10^{-6}$  mbar ( $N_2$ )

## Vacuum basis :

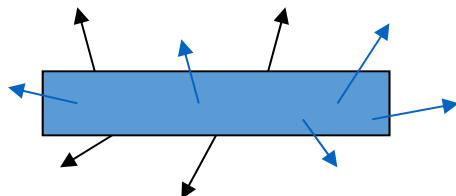
### summary Tables

Pour N<sub>2</sub> at 20°C

Pressure (hPa)	Strength per unit area	density molecular (molecule/cm <sup>3</sup> )	Mean free path	Impingement rate (per cm <sup>2</sup> and per sec)	Monolayer formation time
1013	1 kg/cm <sup>2</sup>	2,50x10 <sup>19</sup>	0,1 μm	2,9x10 <sup>23</sup>	3,4x10 <sup>-9</sup> s
1	1 g/cm <sup>2</sup>	2,47x10 <sup>16</sup>	0,1 mm	2,9x10 <sup>20</sup>	3,4x10 <sup>-6</sup> s
10 <sup>-3</sup>	1 mg/cm <sup>2</sup>	2,47x10 <sup>13</sup>	10 cm	2,9x10 <sup>17</sup>	3,4x10 <sup>-3</sup> s
10 <sup>-6</sup>	1 μg/cm <sup>2</sup>	2,47x10 <sup>1</sup>	100 m	2,9x10 <sup>14</sup>	3,4 s
10 <sup>-9</sup>	10 μg/m <sup>2</sup>	2,47x10 <sup>7</sup>	100 km	2,9x10 <sup>11</sup>	1 heure
10 <sup>-12</sup>	0,01 μg/m <sup>2</sup>	2,47x10 <sup>4</sup>	10 <sup>5</sup> km	2,9x10 <sup>8</sup>	40 jours
10 <sup>-16</sup>	1 μg/km <sup>2</sup>	2,47	10 <sup>9</sup> km	2,9x10 <sup>4</sup>	1000 ans
10 <sup>-23</sup>	10 <sup>-7</sup> μg/km <sup>2</sup>	2,47x10 <sup>-7</sup>	10 <sup>16</sup> km	2,9x10 <sup>-3</sup>	10 <sup>10</sup> ans

## outgassing

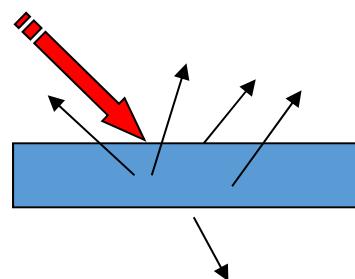
Outgassing is the **spontaneous** evolution of gas from solid or liquid.



## desorption /degazing

Desorption is the release of adsorbed chemical species from the surface of a solid or liquid.

Particules (ions, photons, electrons,...)



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## Desorption: gas flow

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At the thermodynamic equilibrium

Gas flow      
$$Q = P \frac{dV}{dt} = PS = \frac{dN}{dt} KT$$

S effectif pumping speed  
N molecule number

Pa.m<sup>3</sup>/s (=10 mbar.l/s)

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The outgassing rate  $\tau$  : a gas flow per unit of surface

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$$\tau = Q / A$$

A desorption area

$$\text{Pa.m}^3.\text{s}^{-1}.\text{m}^{-2} = \text{Pa.m.s}^{-1} (=10^{-3} \text{ mbar.l.s}^{-1}.\text{cm}^{-2})$$

## Importance of the gas flow

At the thermodynamic equilibrium, the pressure in the system is expressed by:

$$P = \frac{\sum Q}{S} + P_0$$

$P_0$  limit pressure of pumping system  
S effectif pumping speed

Decrease of the work presssure P

⇨ Increase the pumping speed

Approximately 2 to 3 orders of magnitude with a high cost and limited effectiveness conductances

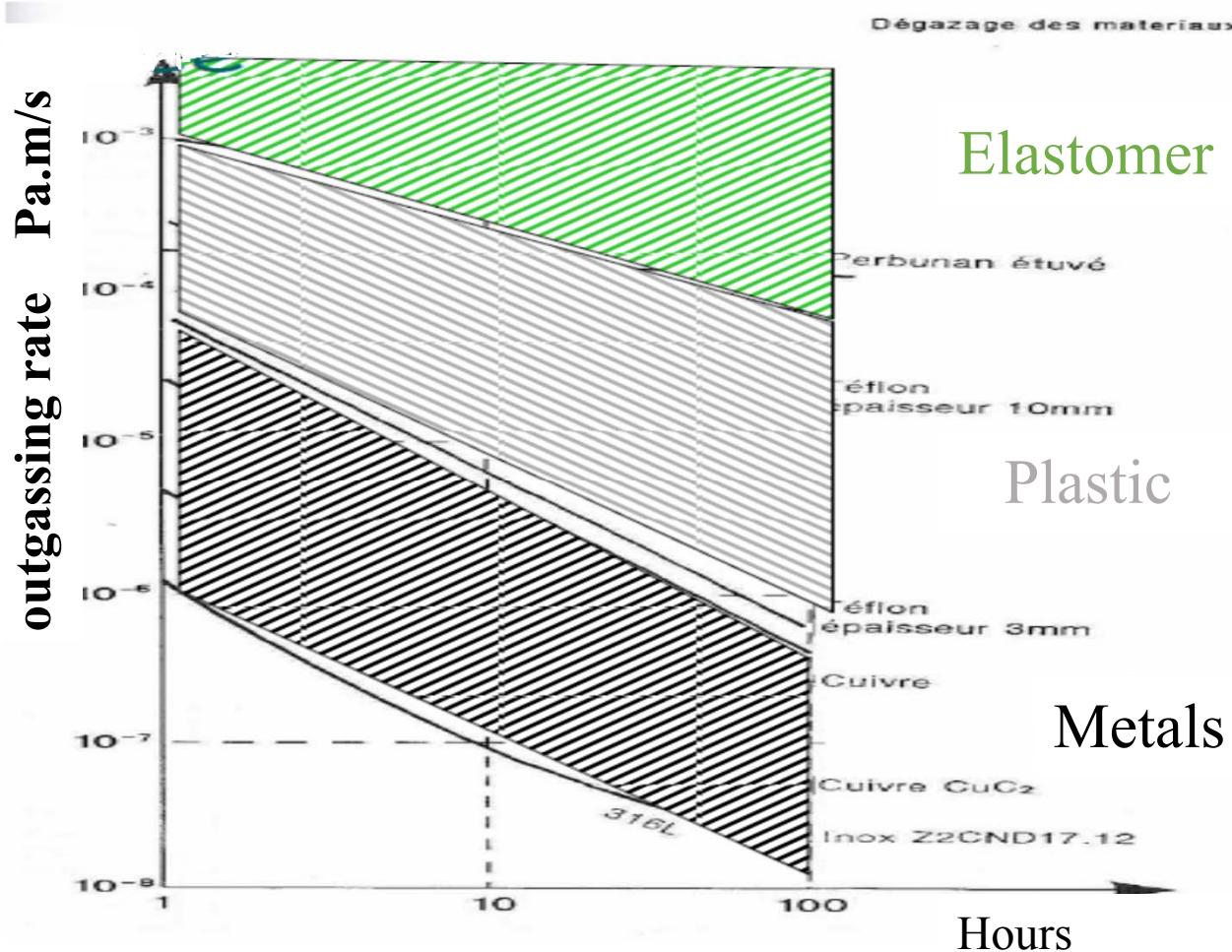
⇨ Decrease the flow

About 10 orders of magnitude depending on the choice of materials and treatments

Attention to minority surfaces

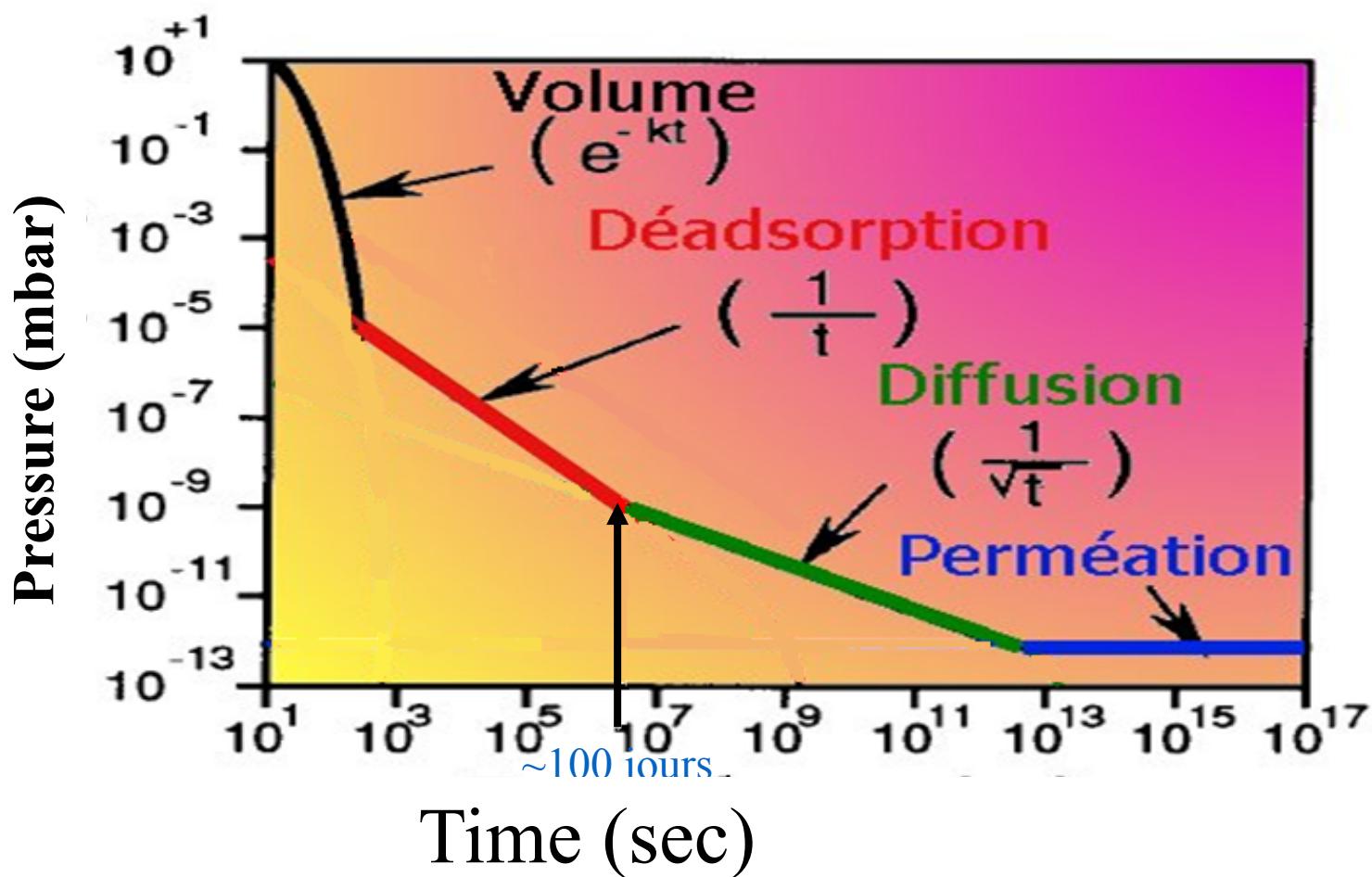
First of all decrease the degassing rates

Time dependance of the outgassing flow rate for different materials

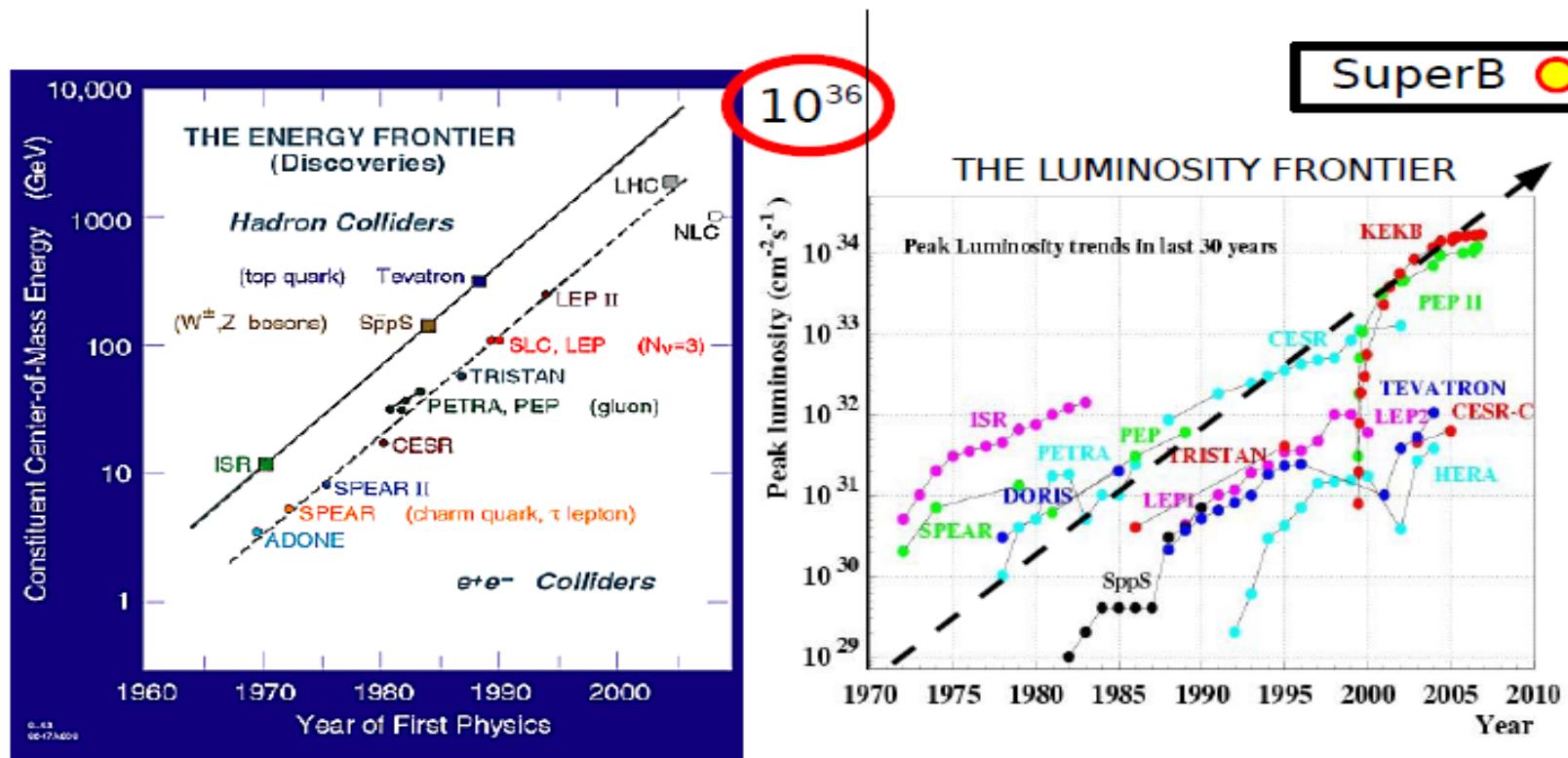


$$1 \text{ Pa.m/s} = 10^{-2} \text{ mbar.l.s}^{-1} \cdot \text{cm}^{-2}$$

The pressure vs. Time behavior of a typical vacuum system (metal chamber)



# Vacuum in accelerators :



$$\mathcal{L} \sim f_{\text{coll}} \frac{N^+ N^-}{4\pi \sigma_x \sigma_y} = 10^{36} \text{ cm}^{-2} \text{ s}^{-1}$$

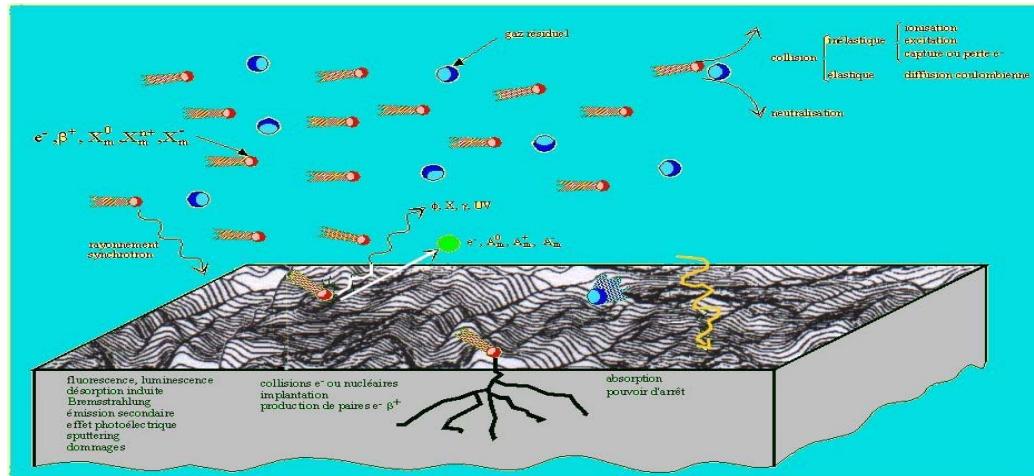
High luminosity

small beam, high intensity and high frequency



Level and quality of the residual gas (dynamic pressure ~ 10<sup>-9</sup> mbar )

# Vacuum in accelerators :



**Beam & Vacuum & Surface:  
a difficult coexistence!**

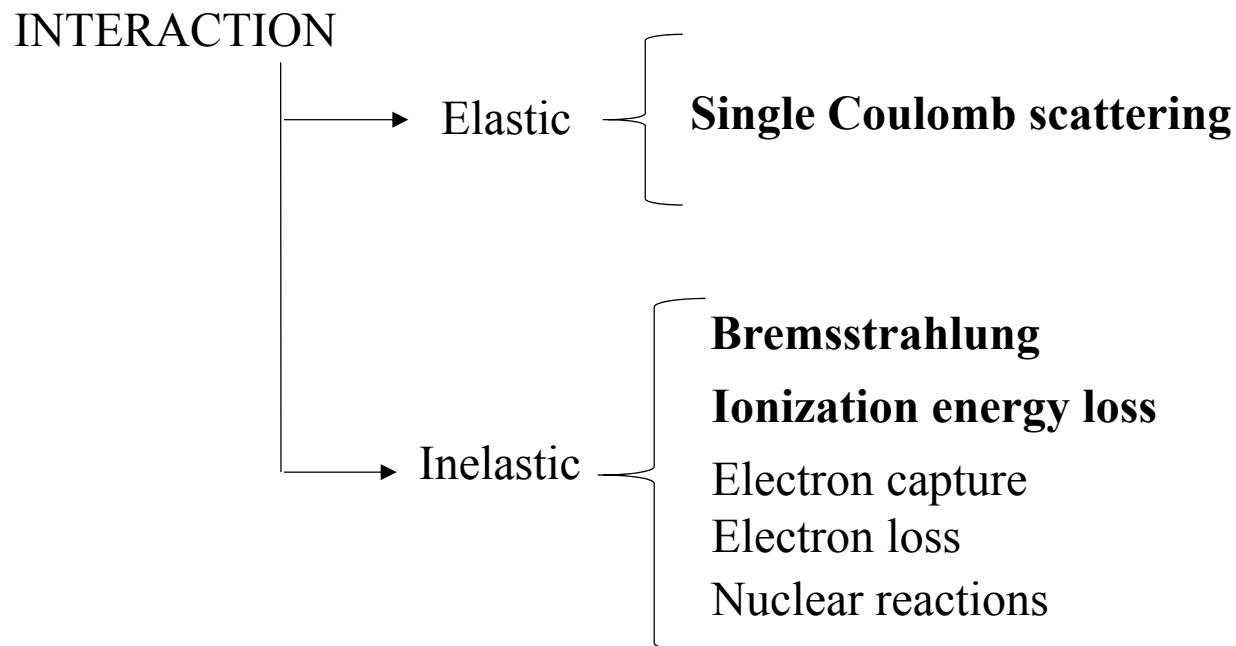
Interaction: Beam - résidual gas

- ➡ Changing the shape and the beam energy
- ➡ Secondary particule emission (ion,  $e^-$ , photons)
- ➡ Loss of beam particules

Interaction: Particules (secondary, primary) - surface

- ➡ Desorption by electron, photon, ion impact
- ➡ Secondary emission

## Interaction: Beam- residual gas



### Interaction: Beam- residual gas

Elastic interaction

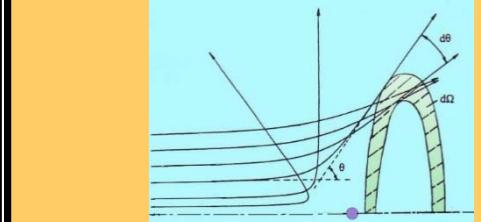
Single Coulomb scattering

$$\frac{d\varepsilon}{dt} \propto Z^2 \cdot P$$

Emittance is proportional to residual gas pressure and depends square residual gas atomic number

#### La Diffusion Coulombienne

$$F = \frac{1}{4\pi\varepsilon_0} \xi_i \xi_c e^2 \frac{\exp(-d/a)}{d^2}$$



$$\sigma_{\theta \max} = 2\pi \left( \frac{\xi_i Z_c e^2}{8\pi\varepsilon_0 m_r v_i^2} \right)^2 \cot g^2(\theta_{\max}/2)$$

Nuclear scattering LHC

Life time limit ~100h P~10-8 mbar H<sub>2</sub> equivalent

80 mW/m heat load in the cold mass

### Interaction: Beam- residual gas

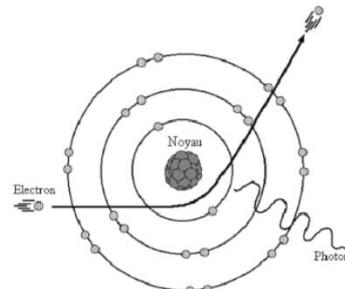
→ Inelastic interaction

**Bremsstrahlung**  
 Ionization energy loss  
 Electron capture  
 Electron loss  
 Nuclear reactions

### Bremsstrahlung

Material	Z	A	Radiation length $X_0$ [g/cm <sup>2</sup> ]	Density [g/cm <sup>3</sup> ] ( $\ell$ ) is for gas [g/ $\ell$ ]
H <sub>2</sub>	1	1.01	61.28	865 0.0708(0.090)
D <sub>2</sub>	1	2.01	122.6	757 0.162(0.177)
He	2	4.00	94.32	755 0.125(0.178)
Li	3	6.94	82.76	155 0.534
Be	4	9.01	65.19	35.3 1.848

Valid for light particules (e<sup>+</sup>,e<sup>-</sup>)



$$\frac{dE}{E} = -\frac{dx}{\chi_0}$$

$$\chi_0[\text{g/cm}^2] = \frac{714.6A_c}{Z_c(Z_c+1)\ln(287/\sqrt{Z_c})}$$

### Loss beam enrgy

the radiation interacts with the surface

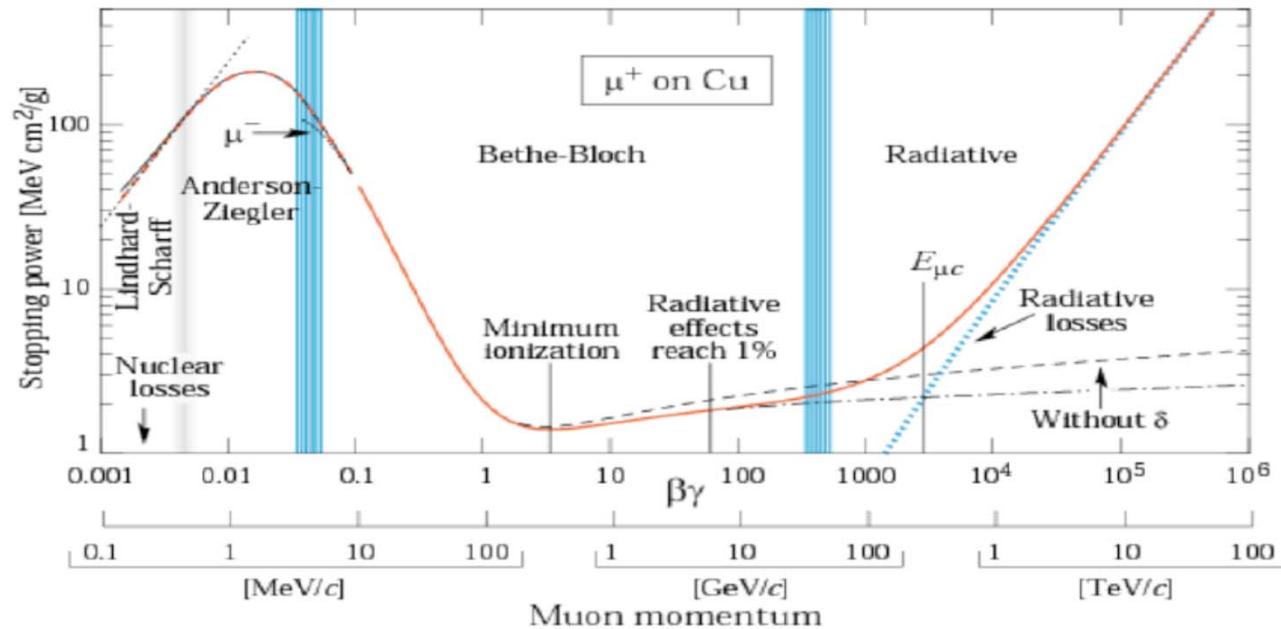


Desorption

A very strong dependence on the target atomic number is observed, which means that even a small amount of a heavy gas may have a higher influence on the lifetime than the usually dominating hydrogen content.  
 about 4.10<sup>6</sup> times lower for proton

### Interaction: Beam – residual gas

#### Ionization energy loss



Loss beam energy

Secondary particule emission: electrons, ions → Interaction on the surface and desorption

### Ion accumulation

negative charge beam

An important phenomenon for negative charges beam, for high current and for short bunch spacing

### Pressure due to the ion containment

#### mechanism:

ionisation of residual gas by beam



Electric field (e- beam) focuses ions in chamber center



Defocusing of ions between two bunch



Oscillations and ions trapping and accumulation

#### consequence:

The pressure (seen by beam) increases



Influence on beam dynamics

## Ion accumulation

Ions stability criterion :Calculation of critical mass<sup>1</sup> :

All ions of mass greater than the critical mass will be accumulated.

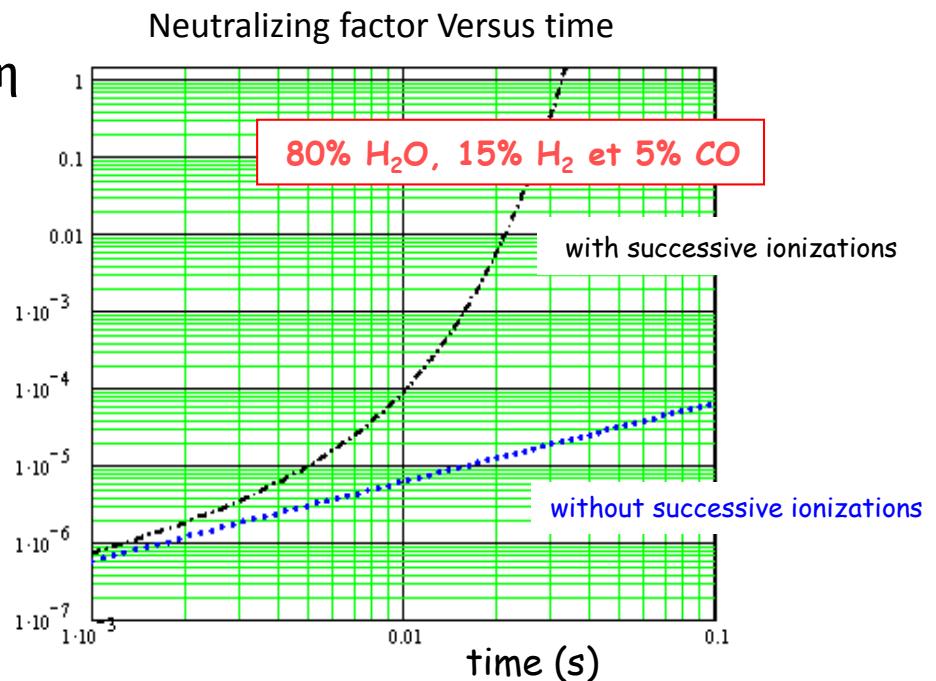
$$A_c = \frac{N_e}{N_b^2} \cdot r_p \cdot \frac{2 \cdot \pi \cdot R}{\beta \cdot b^2 \cdot (1 + a/b)}$$

avec  $N_e$  e- number,  $N_b$  bunch number,  $r_p$  proton radius,  
 $2\pi R$  ring circumference,  $\beta$  ratio of  $v$  to the speed of light  $c$ ,  $a$  and  $b$  beam size .

Neutralizing Factor

$$\eta = \frac{\text{number of positive charge (ions)}}{\text{Number of negative charge (beam electron)}}$$

[1] Neutralisation of accelerator beams by ionisation of the residual gas Y.  
 Baconnier, A. Poncet and P.F. Tavares  
 CERN



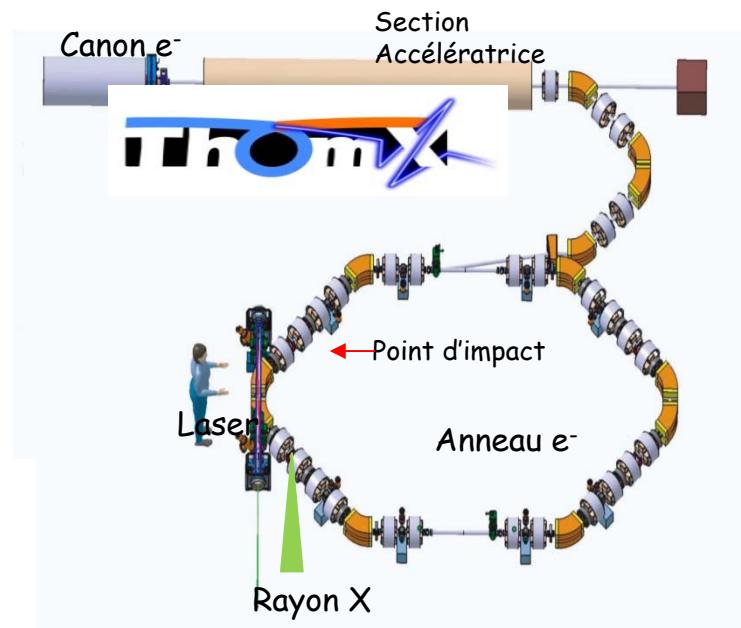
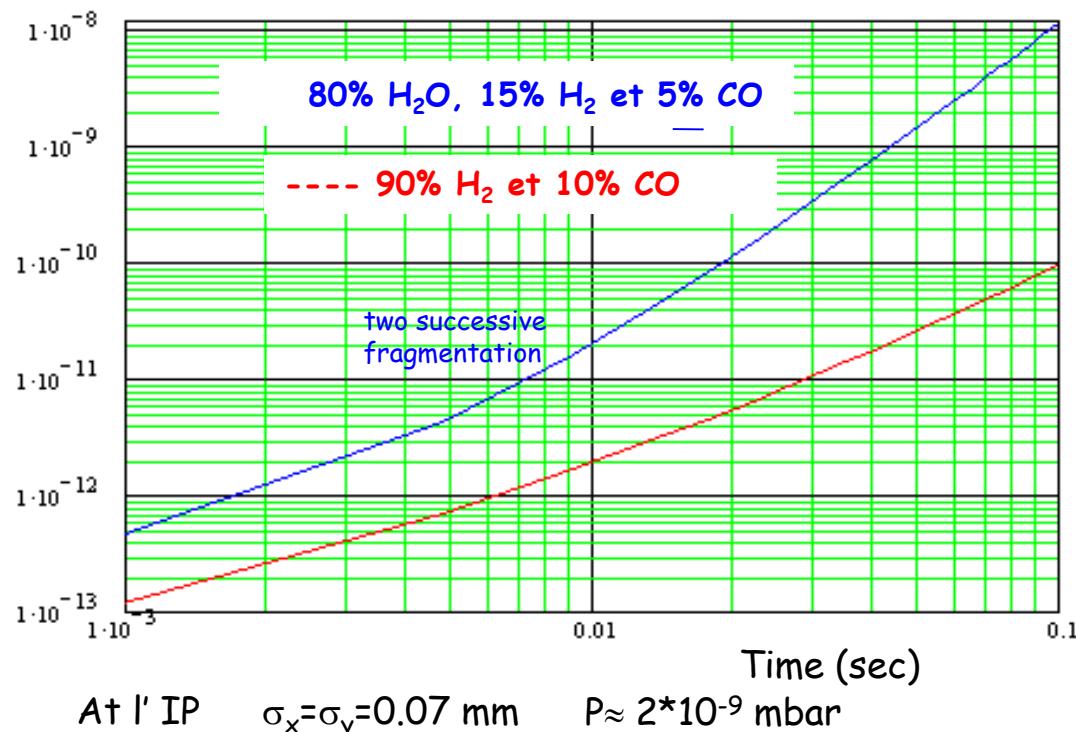
### Ion accumulation

#### Ionic pressure seen by beam

Increased pressure due to the ion density.

$$P_{\text{ion}} = \frac{I \cdot \eta^* \cdot k \cdot T}{e \beta \cdot C \cdot \pi \cdot 2 \cdot \sigma_x \cdot \sigma_y}$$

Ionic pressure (mbar)



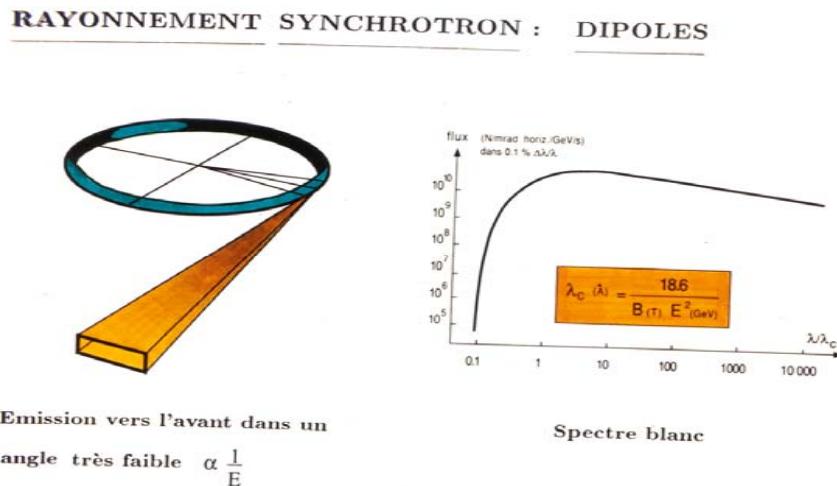
Solutions:

Electrodes + gap between  
two injections ( $5\mu\text{s}$ )

C. Bruni, J. Haissinski, T. Demma

### Synchrotron radiation

Any charged particle undergoing acceleration, centripetal or longitudinal, produces radiation.



Main source on circular colliders

### Power loss

$$\text{electron} \quad P_0 [\text{W/m}] = 88.57 \frac{E[\text{GeV}]^4}{2\pi \rho[\text{m}]^2} I[\text{mA}]$$

$$\text{proton} \quad P_0 [\text{W/m}] = 7.79 \cdot 10^{-12} \frac{E[\text{GeV}]^4}{2\pi \rho[\text{m}]^2} I[\text{mA}]$$

### Critical energy

$$\text{Electrons : } \varepsilon_c [\text{eV}] = 2.218 \cdot 10^3 \frac{E[\text{GeV}]^3}{\rho[\text{m}]}$$

$$\text{Protons : } \varepsilon_c [\text{eV}] = 3.5835 \cdot 10^{-7} \frac{E[\text{GeV}]^3}{\rho[\text{m}]}$$

### Flux

- $\Gamma [\text{photons.m}^{-1}.\text{s}^{-1}] = 1.288 \cdot 10^{17} \frac{E[\text{GeV}]}{\rho[\text{m}]} I[\text{mA}]$

- $\Gamma [\text{photons.m}^{-1}.\text{s}^{-1}] = 7.017 \cdot 10^{13} \frac{E[\text{GeV}]}{\rho[\text{m}]} I[\text{mA}]$

### synchrotron radiation

some examples

		Soleil	KEK-B		LEP			LHC	
			LER	HER	Inj.	1	2	Inj.	Col.
Particule		e <sup>-</sup>	e <sup>+</sup>	e <sup>-</sup>	e <sup>-</sup>	e <sup>-</sup>	e <sup>-</sup>	p	p
Courant	mA	500	2600	1100	3	3	7	584	584
Energie	GeV	2.75	3.5	8	20	50	96	450	7000
R. courbure	m	5.36	16.31	104.46	2962.96			2784.302	
Puissance	W/m	14 030	20 675	5 820	0.8	30	955	0	0.2
En. critique	eV	8 600	5 800	11 000	6 000	94 000	660 000	0	44
Flux	photons/m/s	3 10 <sup>19</sup>	7 10 <sup>19</sup>	1 10 <sup>19</sup>	3 10 <sup>15</sup>	7 10 <sup>15</sup>	3 10 <sup>16</sup>	7 10 <sup>15</sup>	1 10 <sup>17</sup>
Dose a 3000 h	photons/m	4 10 <sup>26</sup>	8 10 <sup>26</sup>	1 10 <sup>26</sup>	3 10 <sup>22</sup>	7 10 <sup>22</sup>	3 10 <sup>23</sup>	7 10 <sup>22</sup>	1 10 <sup>24</sup>

### Photon stimulated desorption

**photodesorption Yield  $\eta$**

$$\eta = \frac{\text{desorbed molecule}}{\text{Incident photons}}$$



material type, surface finish, energy and particle type, incidence angle, particule dose

### Experimental determination

**photodesorption Yield  $\eta$  at machine start-up**

gas	$\eta$ (mol/ph)
H <sub>2</sub>	$\sim 1.10^{-3}$
CH <sub>4</sub>	$\sim 1.10^{-4}$
CO	$\sim 5.10^{-4}$
CO <sub>2</sub>	$\sim 3.10^{-4}$

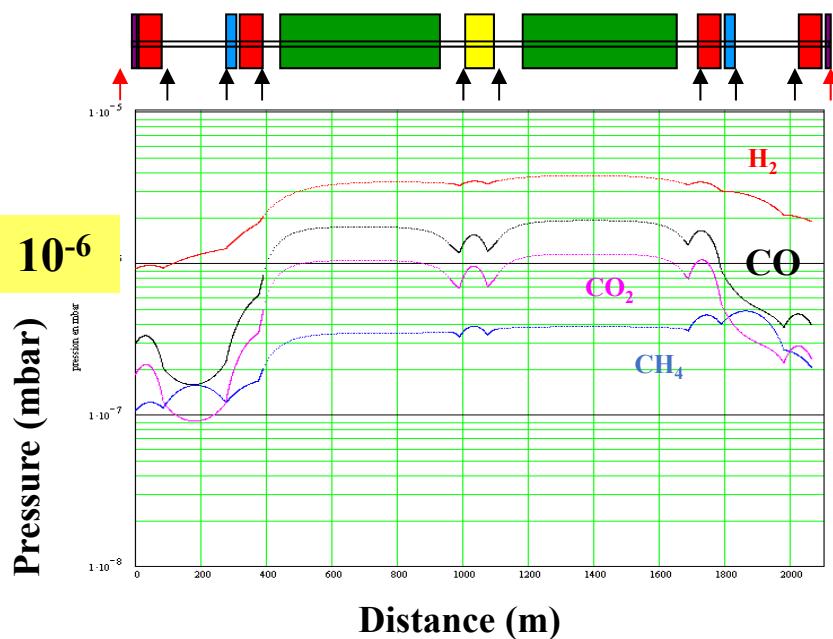


For baked Cu 150°C and Ec = 4,5 Kev

Gröbner and all, JVSTA 12(3) 1994

The static pressure increases by several orders of magnitude due to dynamic effects

**the pressure distribution in Cell HER (SUPERB) with synchrotron radiation at machine start-up**

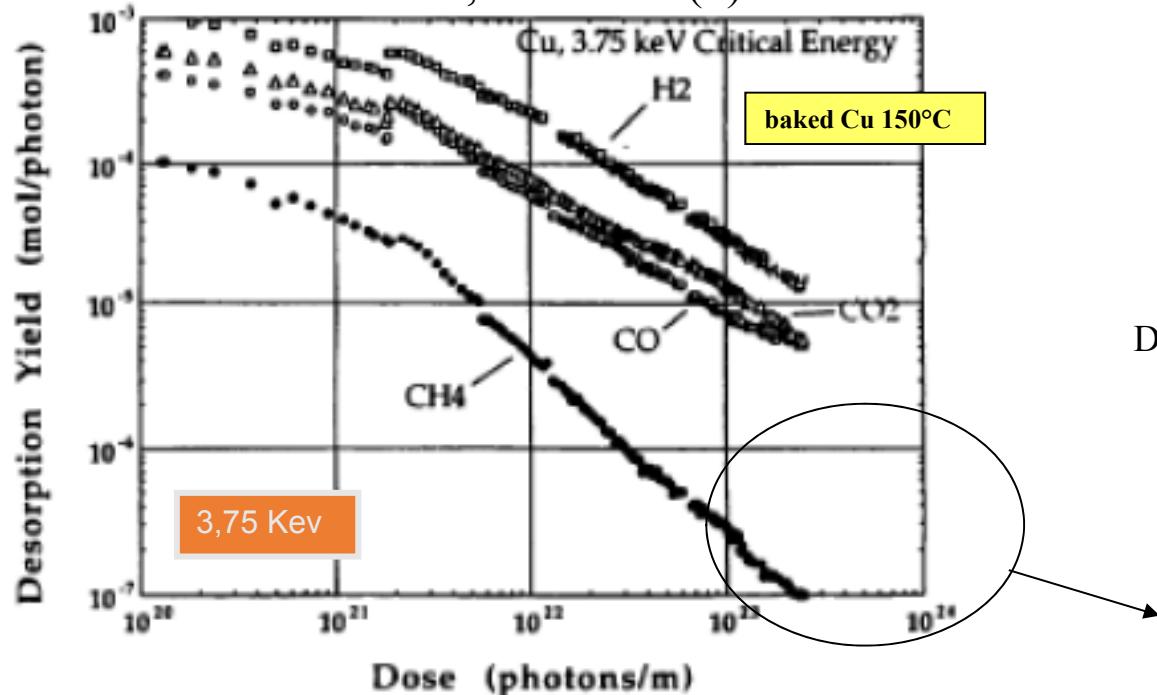


photodesorption

### Conditioning - Scrubbing

Surface conditioning according to the received dose

Gröbner and all, JVSTA 12(3) 1994



After conditionning

D = photon dose  $10^{25}$  photons/m  $\sim 360$  A.h

gas	$\eta$ (mol/ph)
H <sub>2</sub>	$\sim 6.10^{-7}$
CH <sub>4</sub>	$\sim 2.5.10^{-8}$
CO	$\sim 2.5.10^{-7}$
CO <sub>2</sub>	$\sim 2.5.10^{-7}$

$$\eta = \eta_0 \cdot \left( \frac{D}{D_0} \right)^{-\alpha} \quad \alpha = 0.84$$



Scrubbing but needed time

### Photon stimulated desorption

Important implications for the design

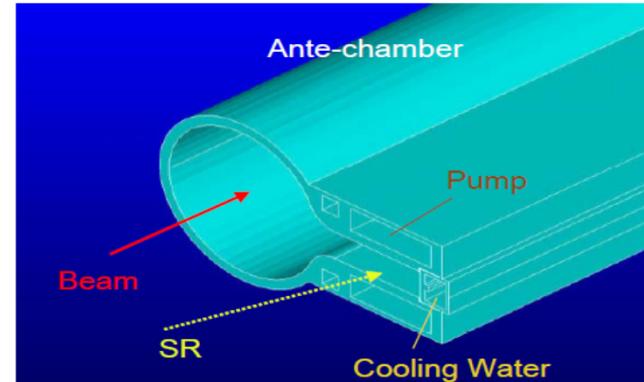
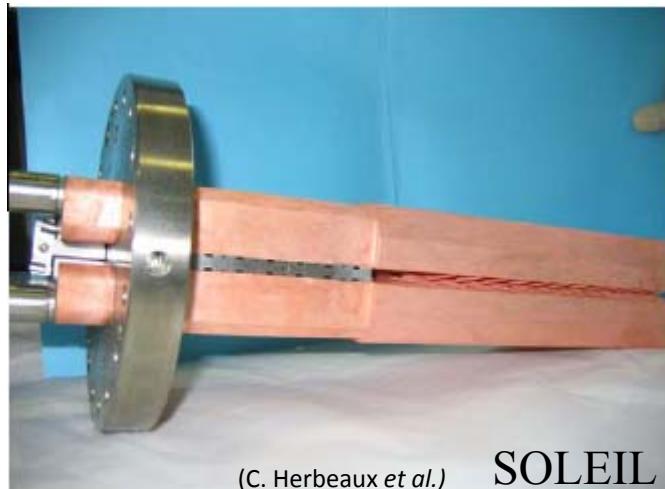
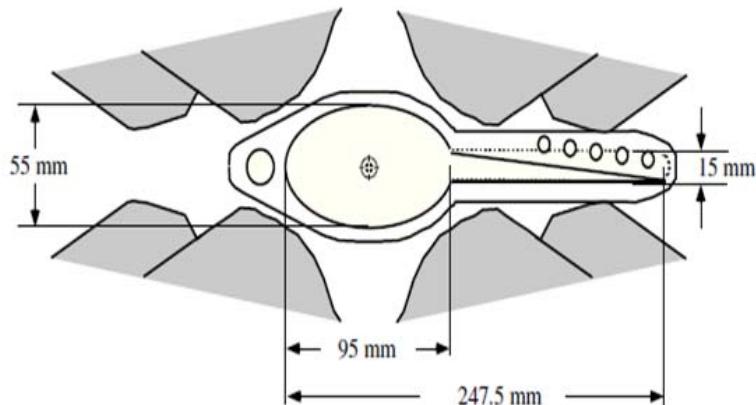


Figure 1: Typical structure of ante-chamber for the LER of Super-KEKB.

### SOLEIL

Puissance	W/m	14 030
En. critique	eV	8 600
Flux	photons/m/s	3 10 <sup>19</sup>

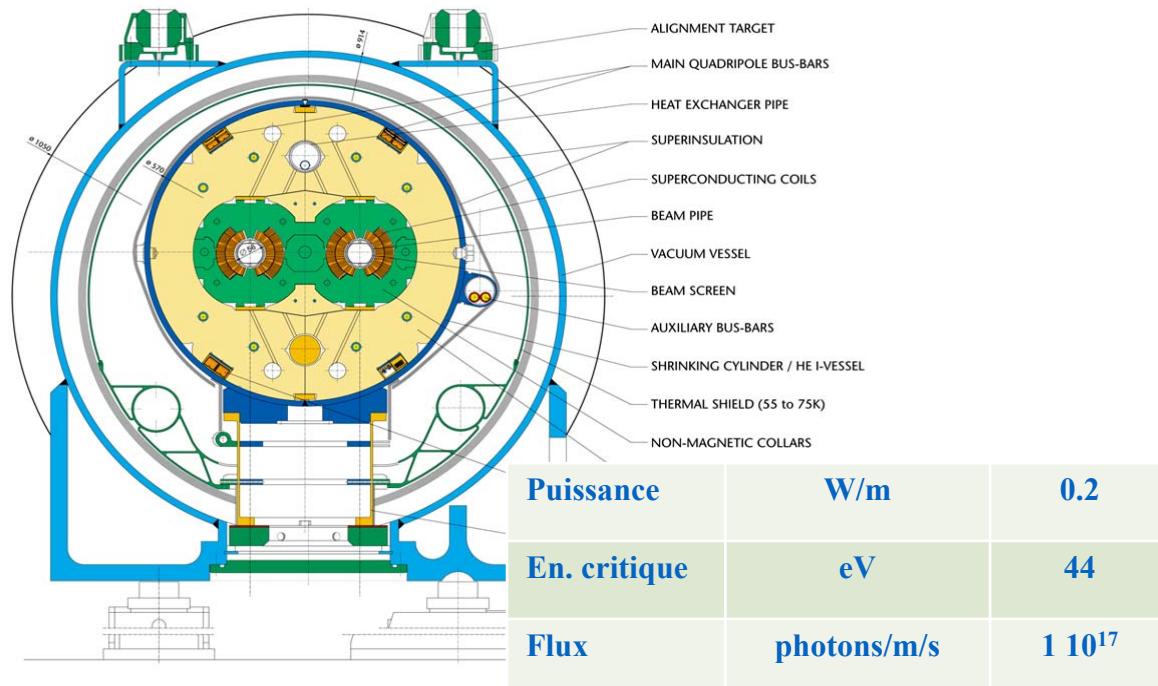
Absorbing power "crotch" : GLIDCOP copper cooled by water(256 W / mm<sup>2</sup>)

### Photon stimulated desorption

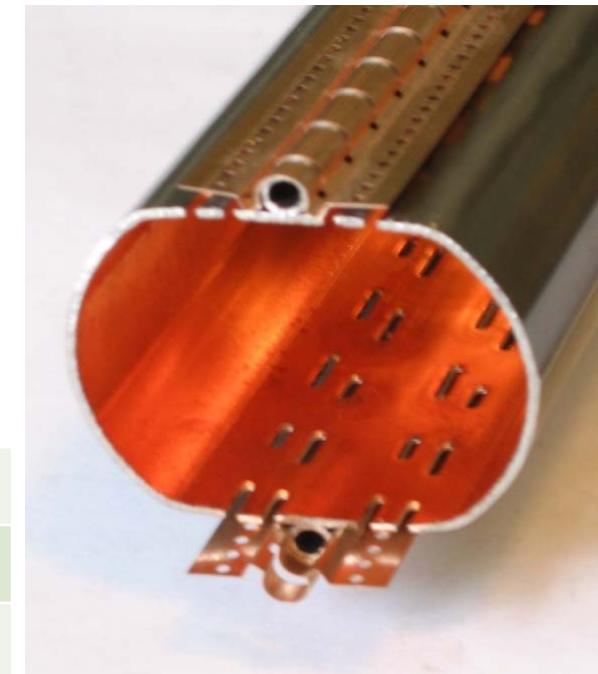
## LHC Dipole Vacuum System

- Cold bore (CB) at 1.9 K which ensures **leak tightness**
- Beam screen (BS) at 5-20 K which intercepts **thermal loads** and acts as a screen

**LHC DIPOLE : STANDARD CROSS-SECTION**



V. BAGLIN



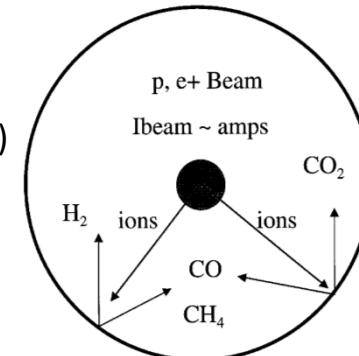
Courtesy N. Kos CERN AT/VAC

### Ion stimulated desorption

### Positive charge beam

The mechanism:

- ionization of the residual gas by the beam
- Acceleration of these ions by the beam electric field (e +, p)
- The ions/surface impact creates a molecular desorption

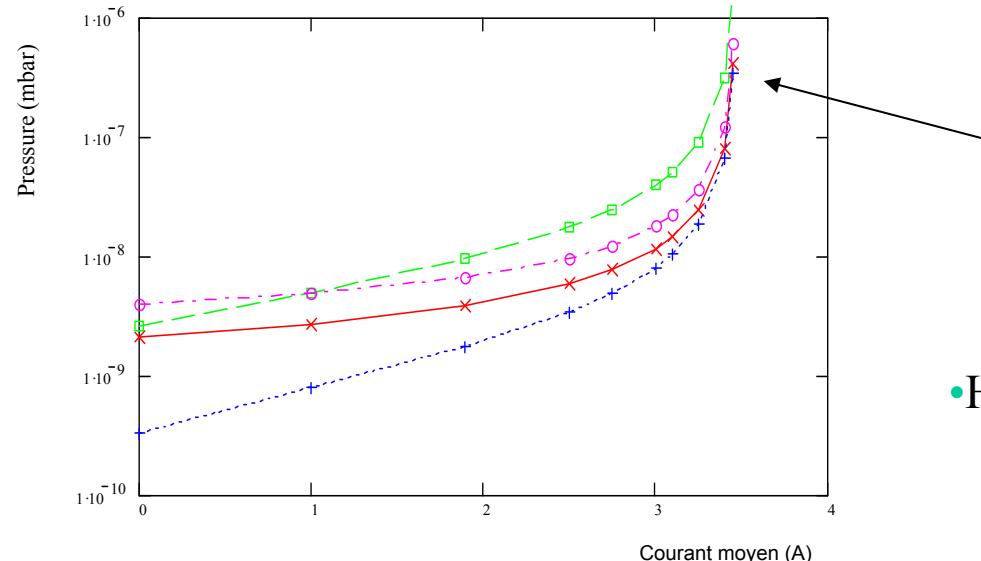


The important parameter

$$\text{Rendement } \eta = \frac{\text{desorption molecular}}{\text{Incident ions}}$$

$$\text{flux: } \Gamma_{\text{ion}} \approx \sigma \frac{I}{e} \cdot \frac{\beta \cdot P}{k \cdot T}$$

### HER (SuperB) simulation



### pressure divergence

$$I_{\text{crit}} \approx \frac{1 eS}{\eta \sigma}$$

- Effectif Pumping speed
- Cross section (Avoid heavy gas)

• High current accelerators : ISR, SNS, LHC...

### Ion stimulated desorption

#### Ionodesorption Yield $\eta$

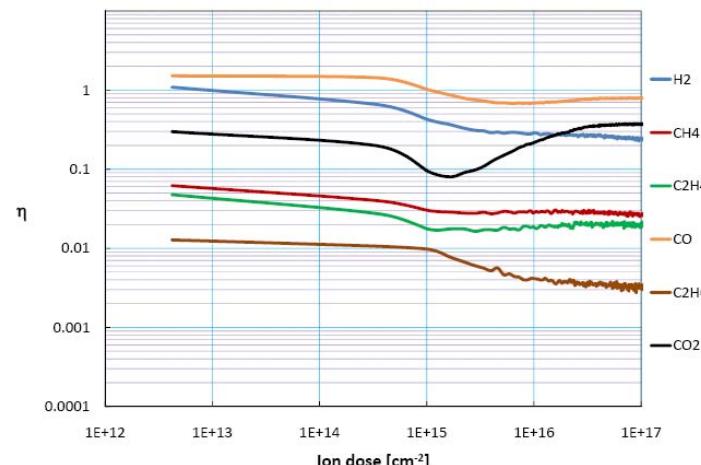


material type, surface finish, energy and particle type, incidence angle, particle dose

Experimental determination

#### $\eta$ versus ion dose

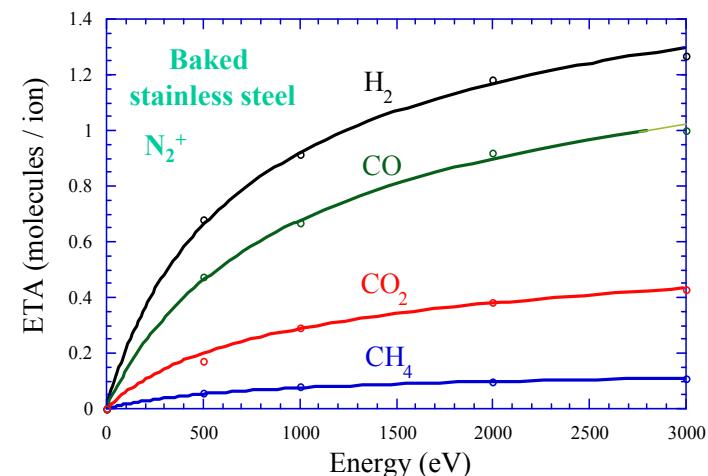
7 keV, Cu Baked,  $\text{CO}^+$



G. Hulla, PhD Thesis, Vienna Tech. U, 2009

LHC : ion dose  $\sim 3 \times 10^{15}$  ions/ $(\text{cm}^2 \cdot \text{an})$

#### $\eta$ versus energy



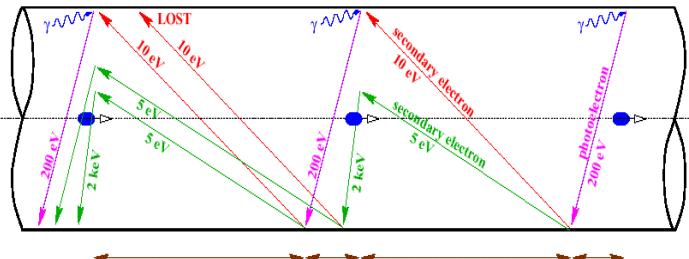
A.G. Mathewson, CERN ISR-VA/76-5

Inefficient scrubbing !!

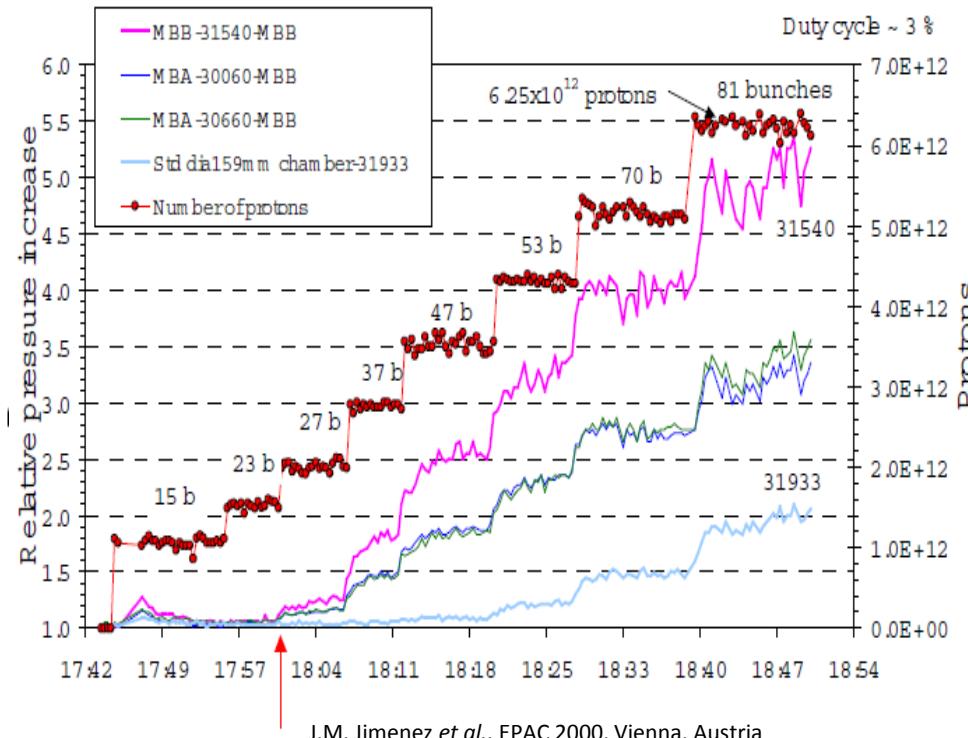
# Vacuum in accelerators :

## Electron-Cloud / Electron Stimulated Desorption

The mechanism:



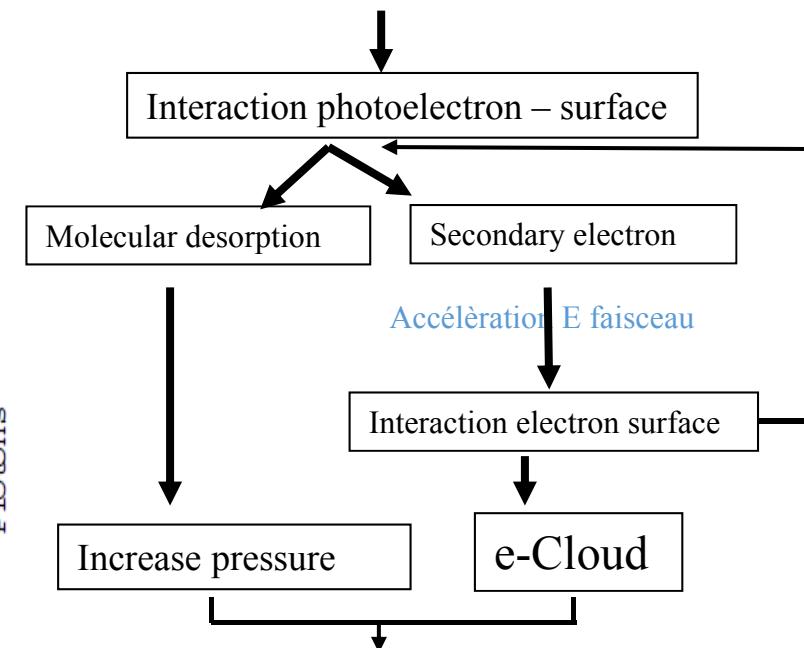
F. Ruggiero et al., LHC Project Report 188 1998, EPAC 98



interaction particules- surface

KEKB, PEP II, SPS ~ année 2000  
RHIC, LHC

photoelectrons acceleration (with electron coming from ionization) by the beam field E



Increase emittance and beam loss, heat load, decrease luminosity

### Electron-Cloud / Electron Stimulated Desorption

An important phenomenon for positive charges beam, for high current and for short bunch spacing

#### Main parameters:

- Beam structure(size,time between bunch)
  - bunch/charge
  - chamber size and geometry
- secondary electron yield (SEY)
  - photo-electrons rate
  - photons /electrons reflected
- electron stimulated desorption (ESD)



#### Some Solutions

- material (coating), surface finish, scrubbing,
- Cleaning electrodes, solenoidal field,
- Geometry chamber (antichamber)

### Electron-Cloud / Electron Stimulated Desorption Surface conditionning by electron impingement (Scrubbing)

#### Electron Stimulated Desorption (ESD)

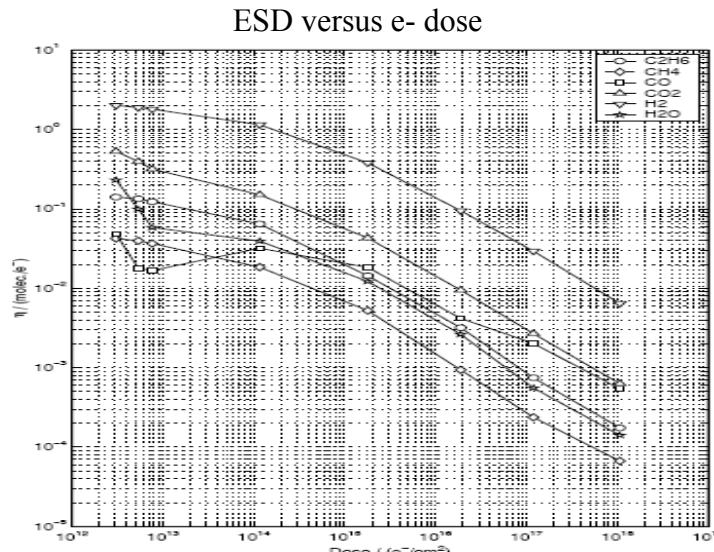


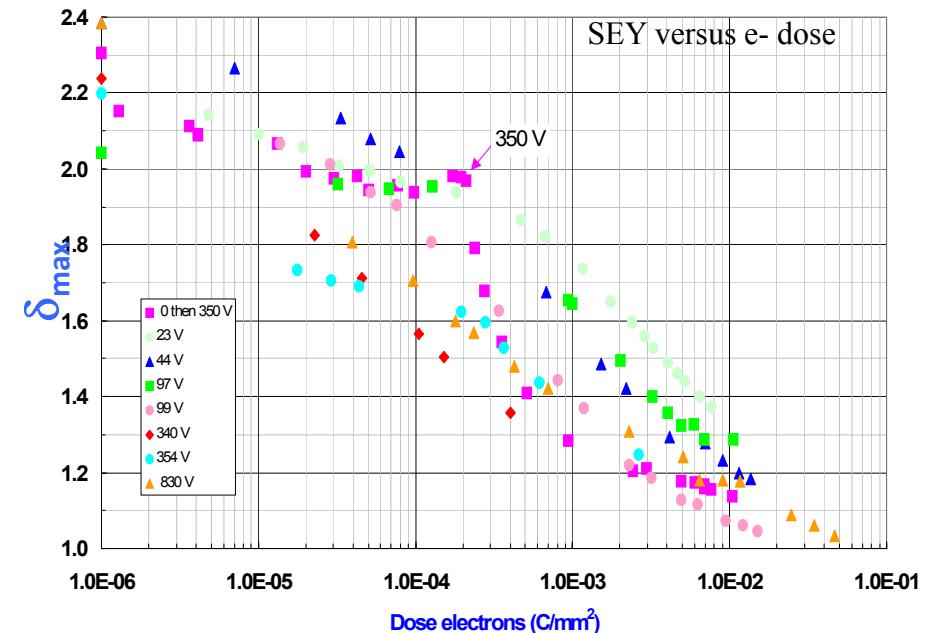
Figure 3: Effect of the electron dose on the electron induced desorption yield of an unbaked copper sample. The electron energy during bombardment and measurement was 300 eV.

G. Vorlauffer et al., CERN VTN, 2000

#### Reduction ESD and SEY

#### Secondary electron yeld (SEY)

$$\text{SEY} = \frac{\text{number of emitted electrons (secondary)}}{\text{number of impinging electrons (primary)}}$$



V. Baglin et al., Chamonix, 2001

Carbone layer on surface (AES, XPS,..)

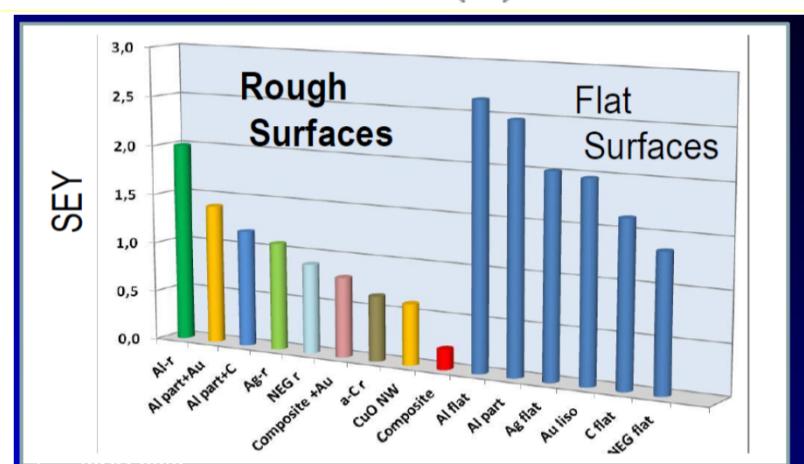
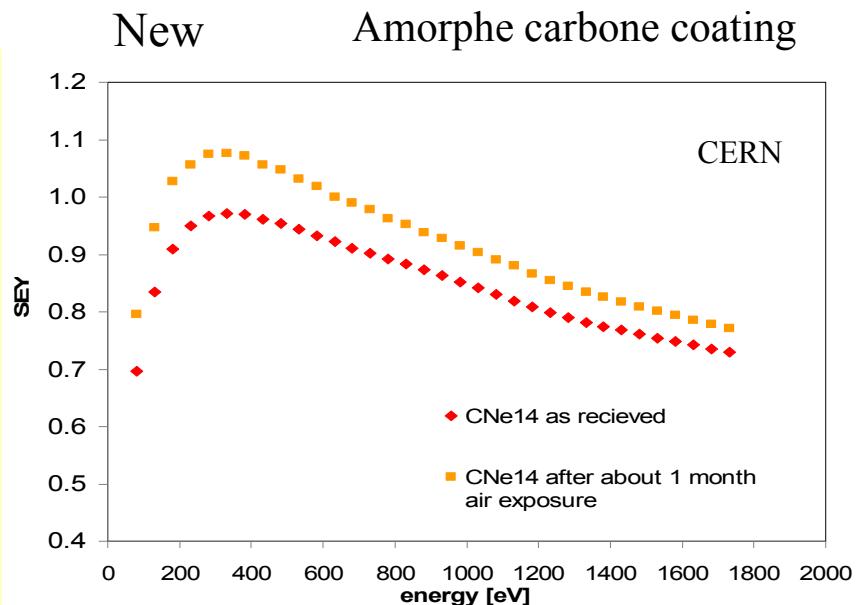
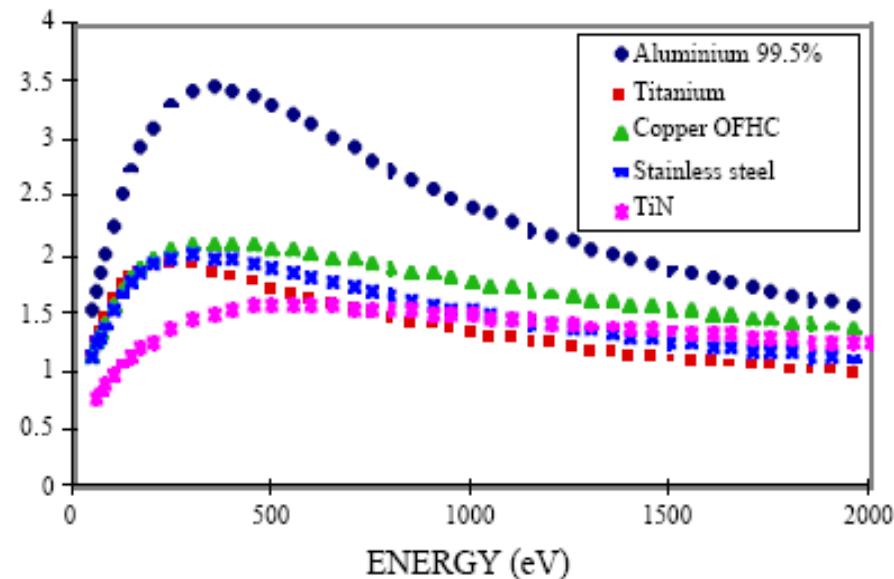


Scrubbing but needed time

### Electron-Cloud / Electron Stimulated Desorption

### SEY Reduction

#### Material and relief surface



Coating TiN, TiZrV, amorphe C coating on vacuum chamber

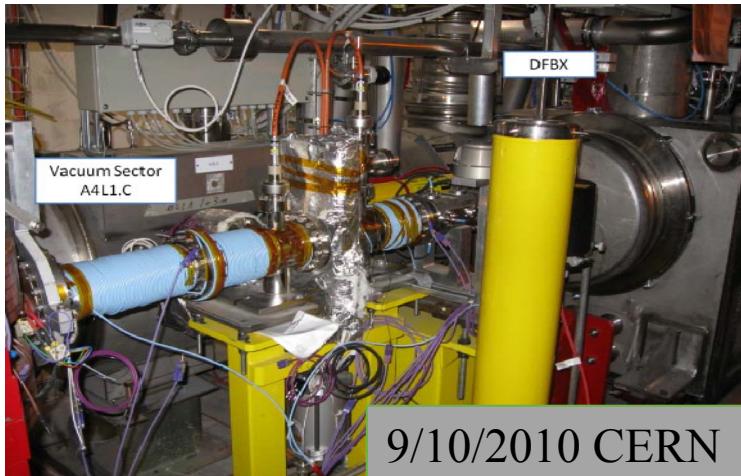
Isabel Montero, ICMM-CSIC (AEC 2012)

# Vacuum in accelerators :

Electron-Cloud / Electron Stimulated Desorption

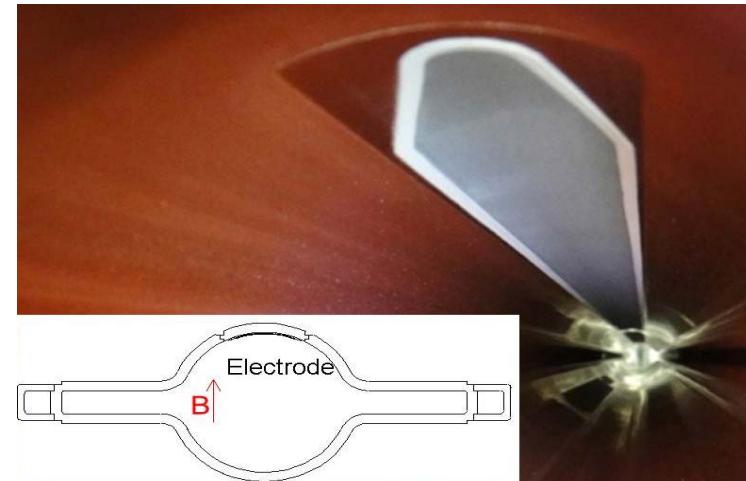
interaction particules- surface

## External solenoid on chamber



## Other solution for e-Cloud decrease

### Clearing electrodes



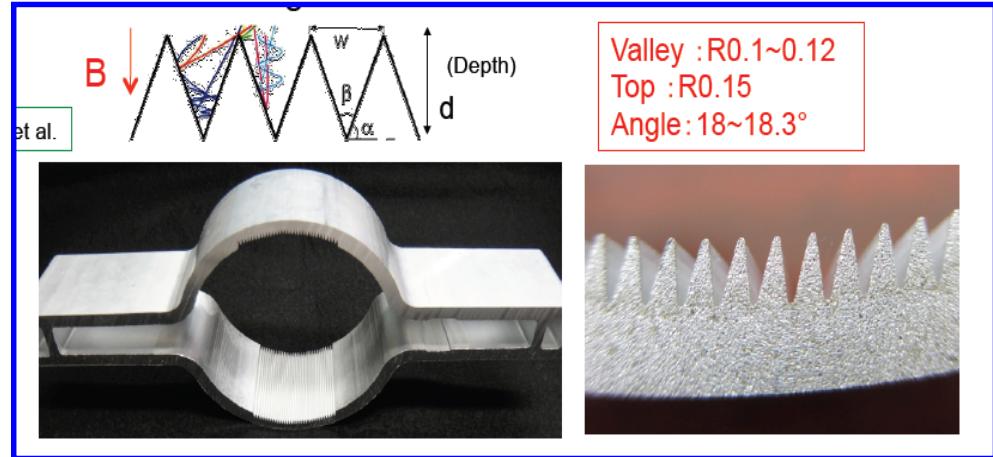
Y. Suetsugu SuperKEKB

Antichamber and Rough surface at the side wall ( $R_a \sim 20$ ) reduces the photon reflection.



Y. Suetsugu SuperKEKB SuperKEKB Dipole Chamber Extrusion

### antichamber, grooves and coating TiN



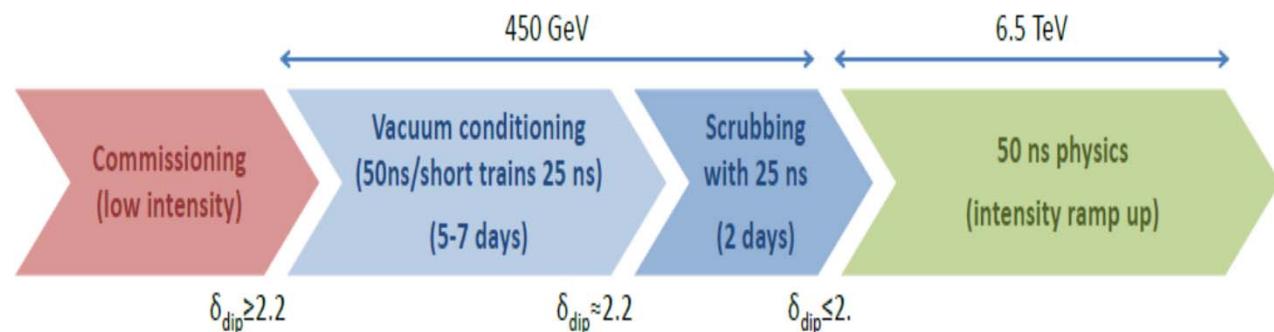
### Electron-Cloud / Electron Stimulated Desorption

LHC

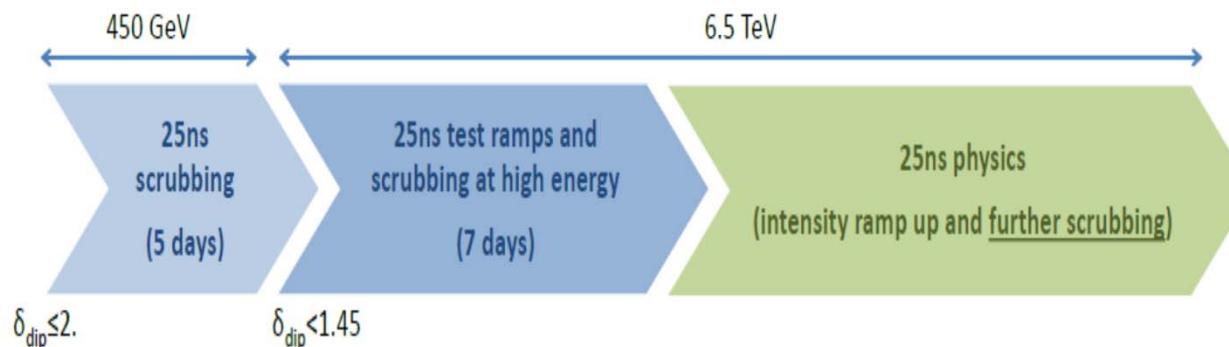
### Scrubbing strategy for operation restart in 2015

#### Requirements for operation with 50 ns beams:

After the 2013-14 Long Shutdown, the Secondary Electron Yield of the beam screen in the arcs will likely be reset to values higher than 2.3, as it was before the 2011-2012 machine scrubbing.



#### Further requirements for operation with 25 ns beams:

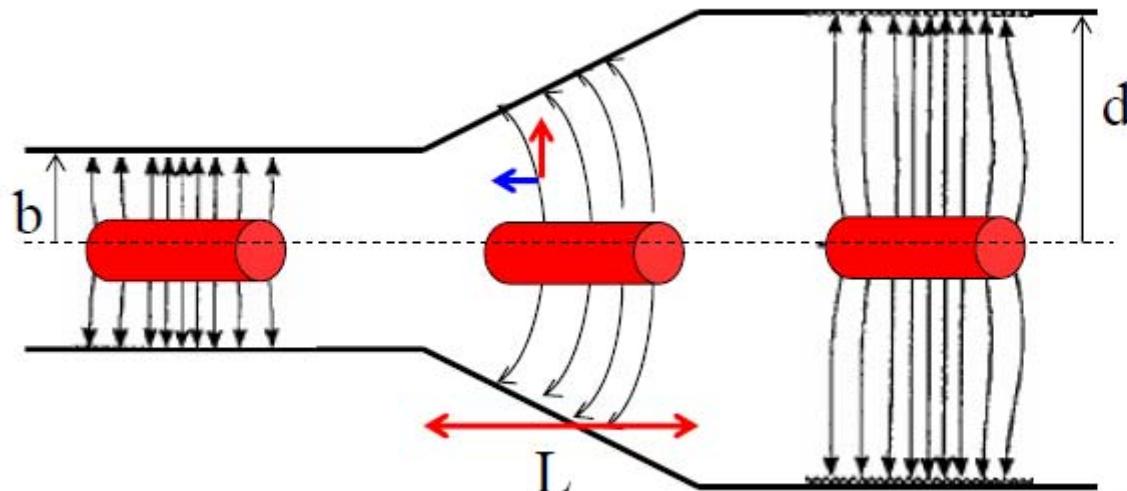


According to the 2012 experience, the proposed scrubbing run(s) will not completely suppress the EC in the LHC. Further scrubbing will have to be achieved during the physics run implying a slow down of the intensity ramp-up process due to heat load, emittance blow up and poor lifetime.

es/  
n

**Electric field Interaction -surface**

Nonzero Impédance of the chamber



M. Ferrario – CAS Baden 2005

Accentuate by section changes, discontinuity ..

Power dissipated on the surface

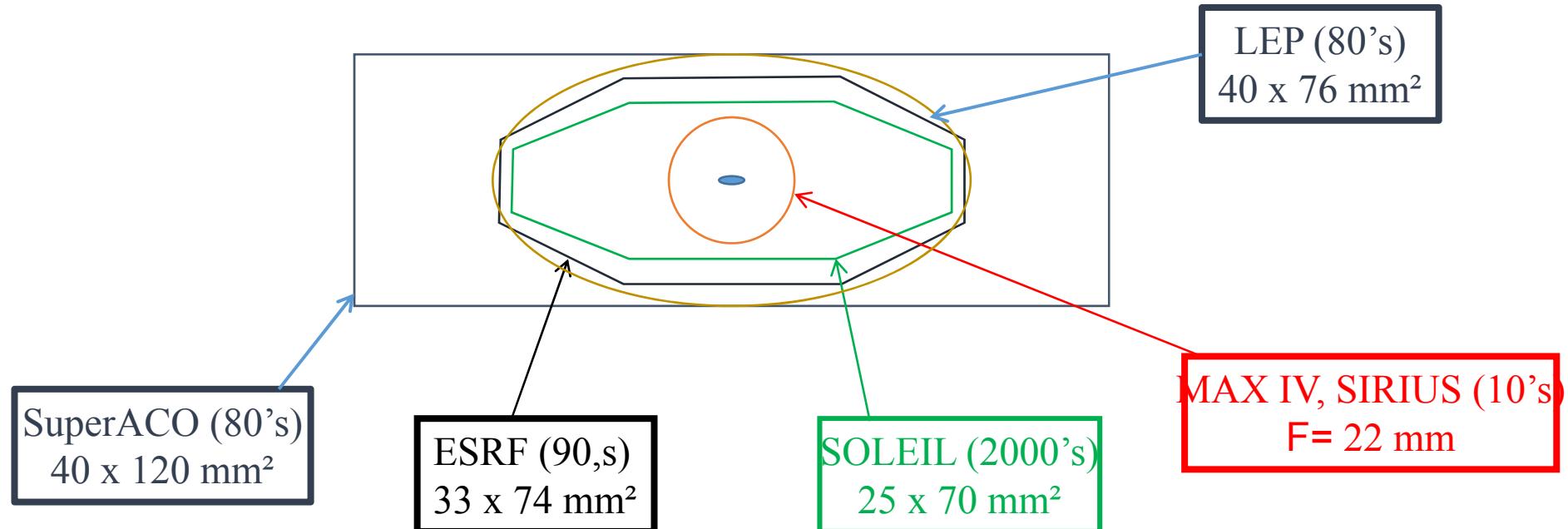
Molecular desorption  
Beam instability

# Evolution vacuum technology

size evolution of vacuum chambers on Accelerators

Size vacuum chambers are constrained by the beam of performance expected by the magnetic system including:

- Strong focus therefore reduces throat circle
- Low distance between the magnets.

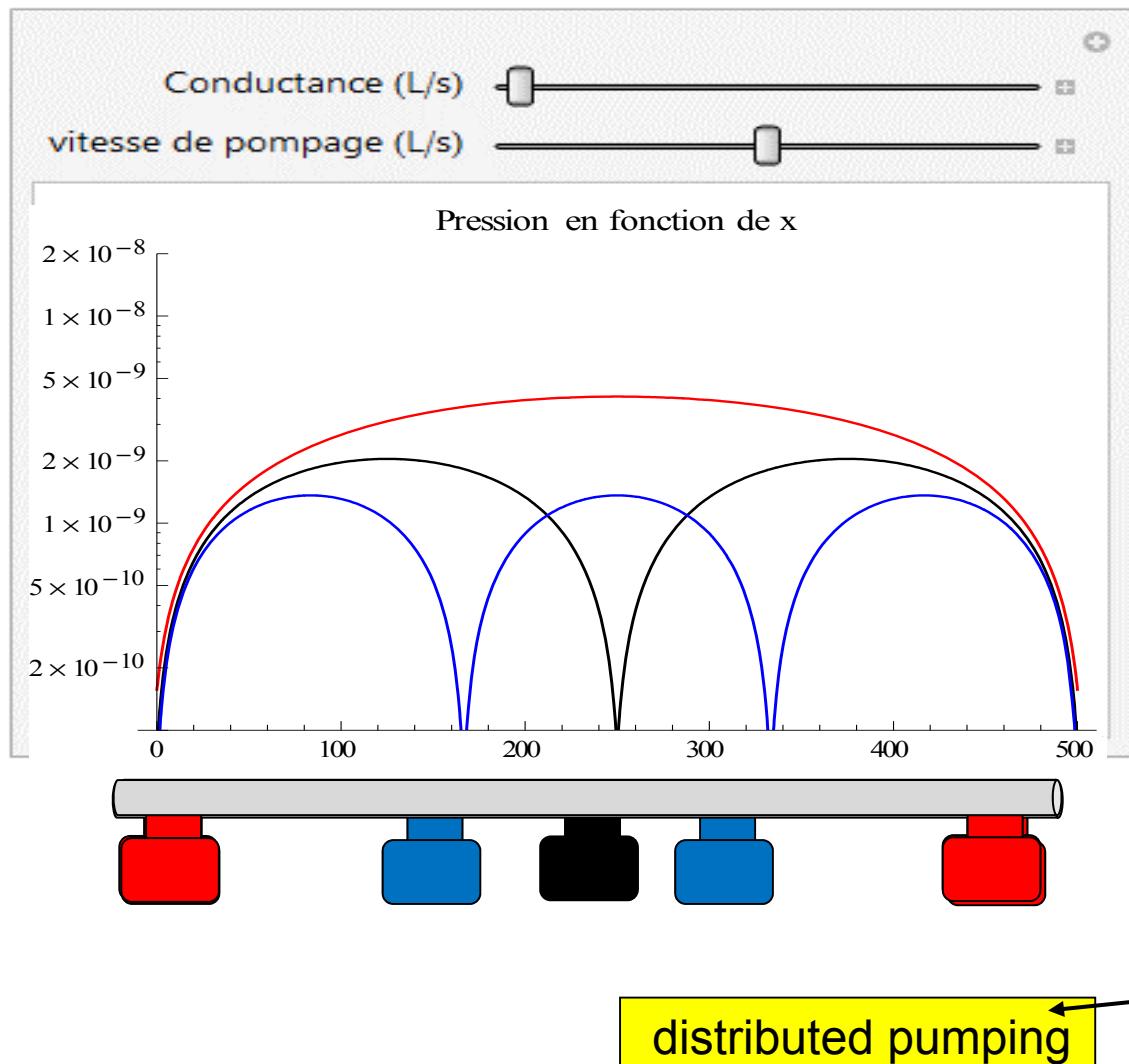


C. Herbeaux SFP – Journées des accélérateurs, Roscoff, SFP 2013

# Evolution vacuum technology

Consequences : size room more and more small

Significant decrease in conductance and increasing the maximum pressure



$$P_{mean} = A \cdot \tau \cdot L \left( \frac{1}{12C} + \frac{1}{S} \right)$$

$$P_{max} = A \cdot \tau \cdot L \left( \frac{1}{8C} + \frac{1}{S} \right)$$

$\tau$  outgassing rate      C conductance

A circumference of chamber

if  $S \gg 8C$  then  $P_{max} \sim A\tau L/(8C)$

**Decrease of Pmean and Pmax is limited by the conductance C :**

- Reduce outgassing rate ( $\tau$ ) and the stimulated desorption
- Reduce length L

# Evolution vacuum technology

## distributed pumping

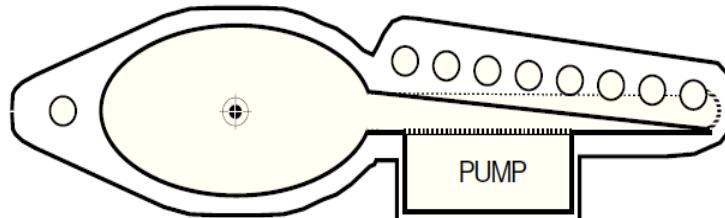
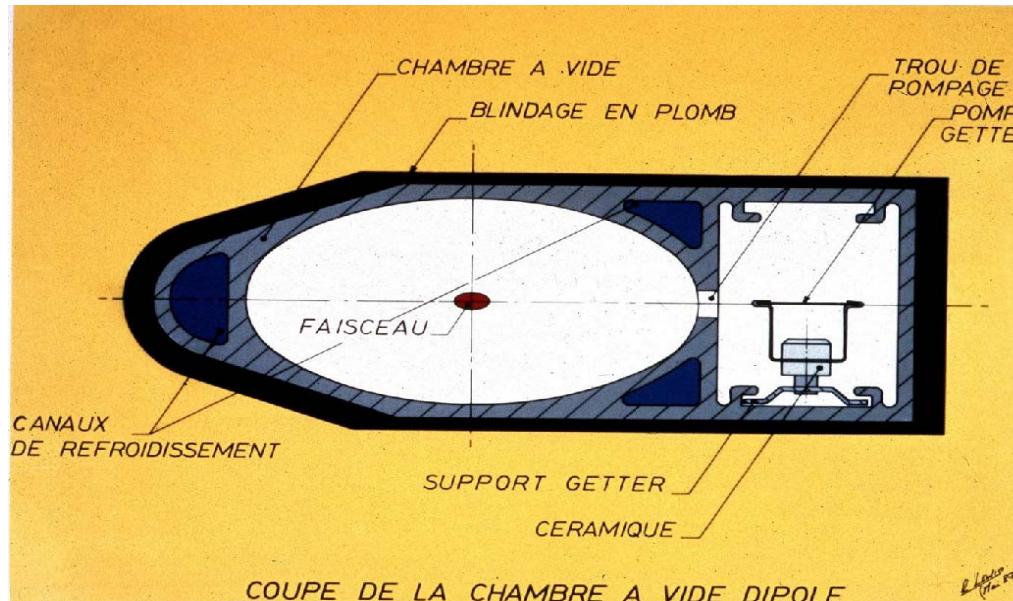
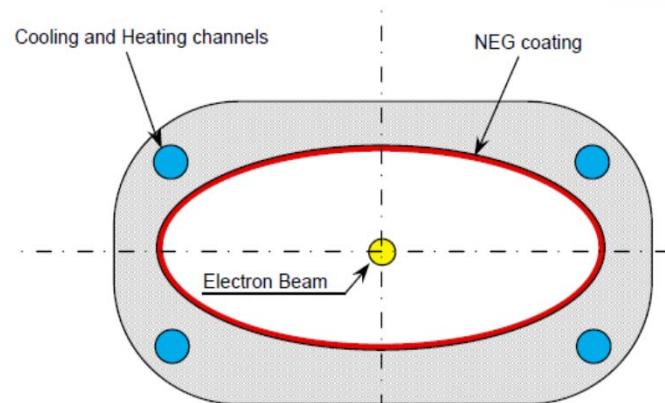
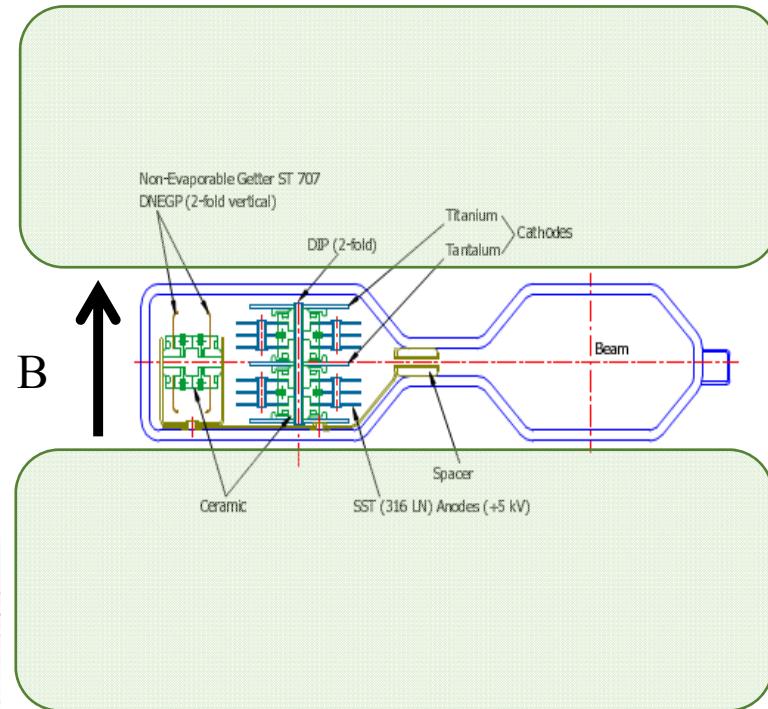


Figure 3-108. LER dipole vacuum chamber concept. Inside dimensions match those of Fig. 3-107.



LEP Design

(CERN LEP Vacuum group)



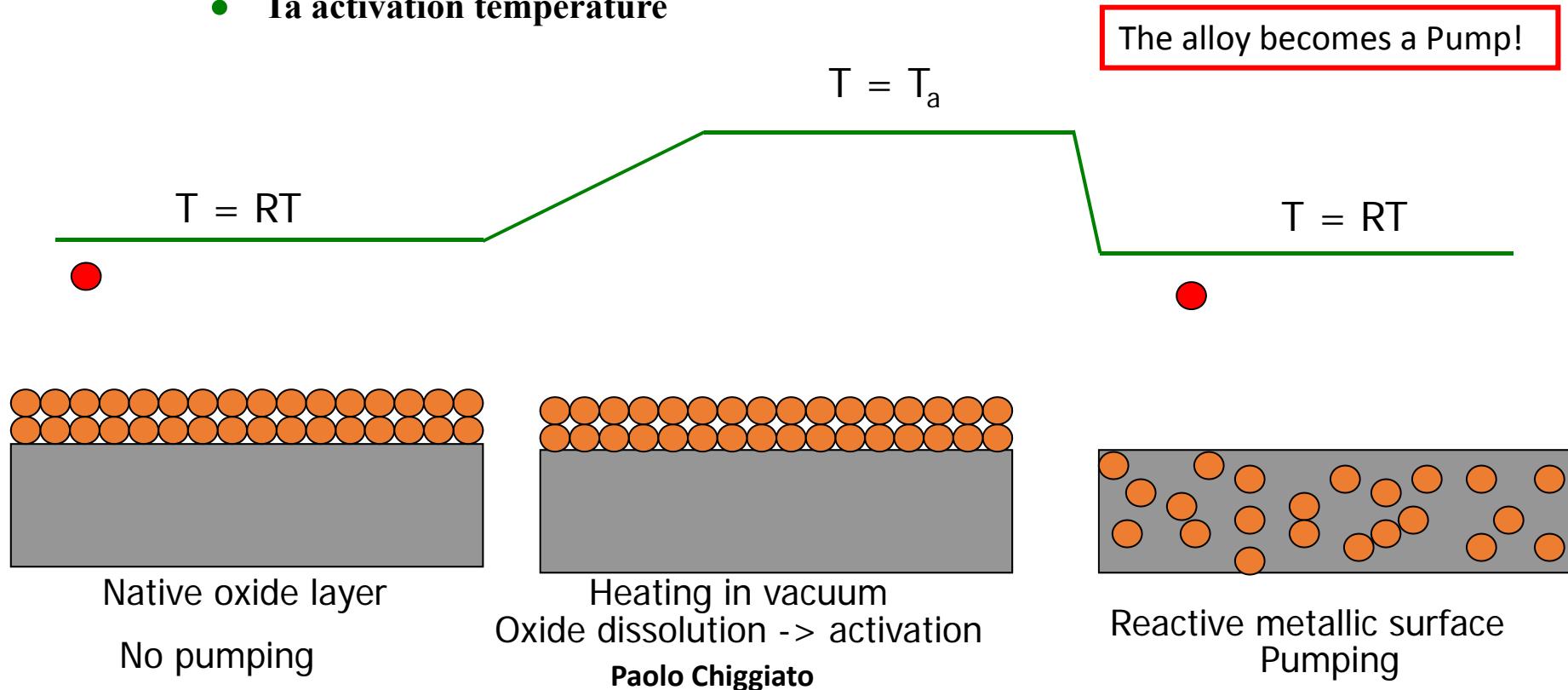
LHC

### Non evaporable Getter (NEG)

#### Principle

coating of metal alloy (NEG) on the walls of vacuum chambers or on a strip

- coating Zr-Al, Zr-V-Fe, Ti-Zr-V, ....
- Ta activation temperature



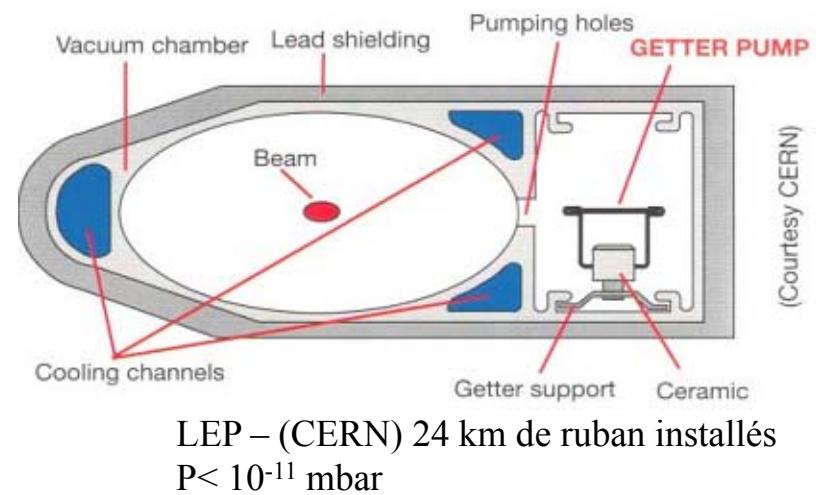
CERN European Organization for Nuclear Research

### NEG strips

**St101 NON-EVAPORABLE GETTER (Zr Al)**  
activation temperature at 700°C

**St707 NON-EVAPORABLE GETTER (Zr 70-V  
24.6-Fe 5.4 wt%)**  
activation temperature at 450°C

NEG materials are embedded in a constantan ribbon that is heated by the Joule effect



**The high temperature activation NEG can generate mechanical stresses in the vacuum chamber.**

**Need to have an antechamber**

# NEG strips

## Design and construction of the SuperKEKB vacuum system

Yusuke Suetsugu,<sup>a)</sup> Ken-ichi Kanazawa, Kyo Shibata, Takuya Ishibashi, Hiromi Hisamatsu, Mitsuru Shirai, and Shinji Terui  
*High Energy Accelerator Research Organization (KEK), Tsukuba, Ibaraki 305-0801, Japan*

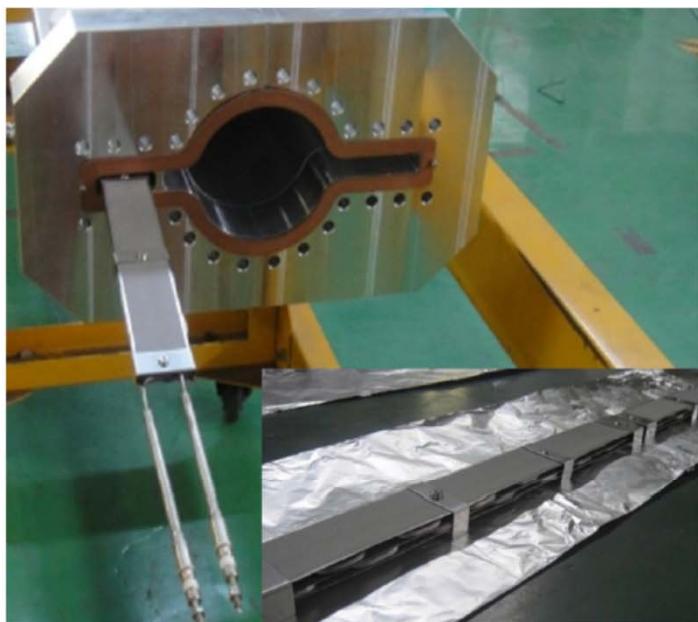


FIG. 4. (Color online) Multilayered NEG strips for the antechamber.

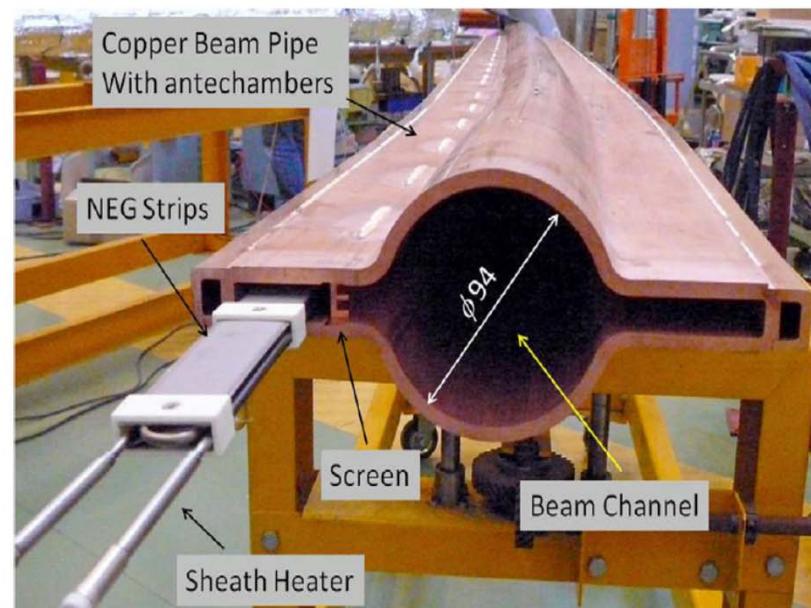


Fig. 1. Example of a beam pipe with antechambers and distributed pumps.

## St707 NON-EVAPORABLE GETTER

J. Vac. Sci. Technol. A, Vol. 30, No. 3, May/Jun 2012

### NEG coating in vacuum chamber

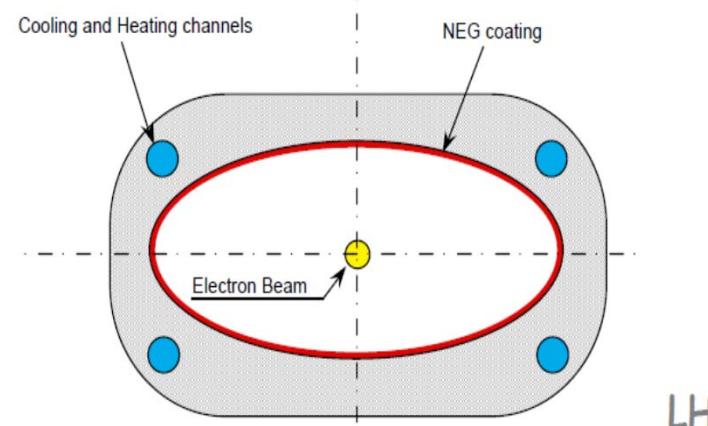
- Titane Zirconium Vanadium coating
- Low activation temperature  $T_a=180^\circ\text{C}$

surface of vacuum chamber becomes a pump!!!

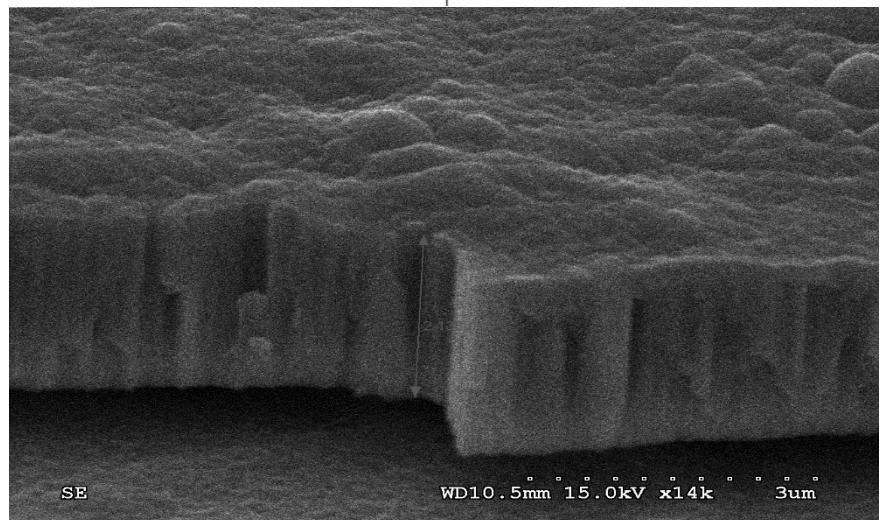
SOLEIL: NEG 60 % of the circumference

LHC : 6 km in warm part

MAX IV: 95% of the circumference



LHC

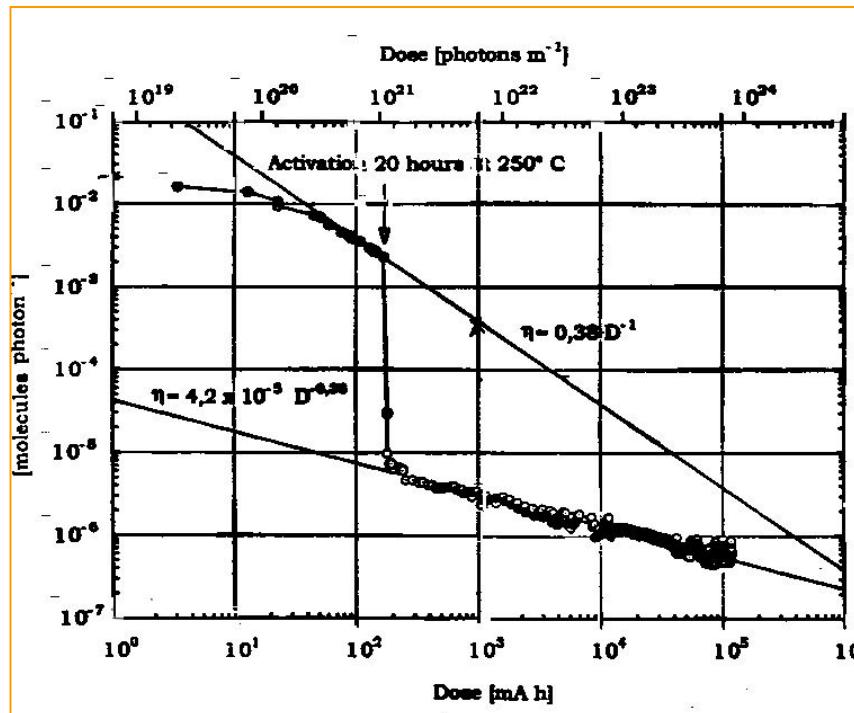


Coating at LAL ( $\sim 2 \mu\text{m}$ )

# NEG coating-vacuum performances

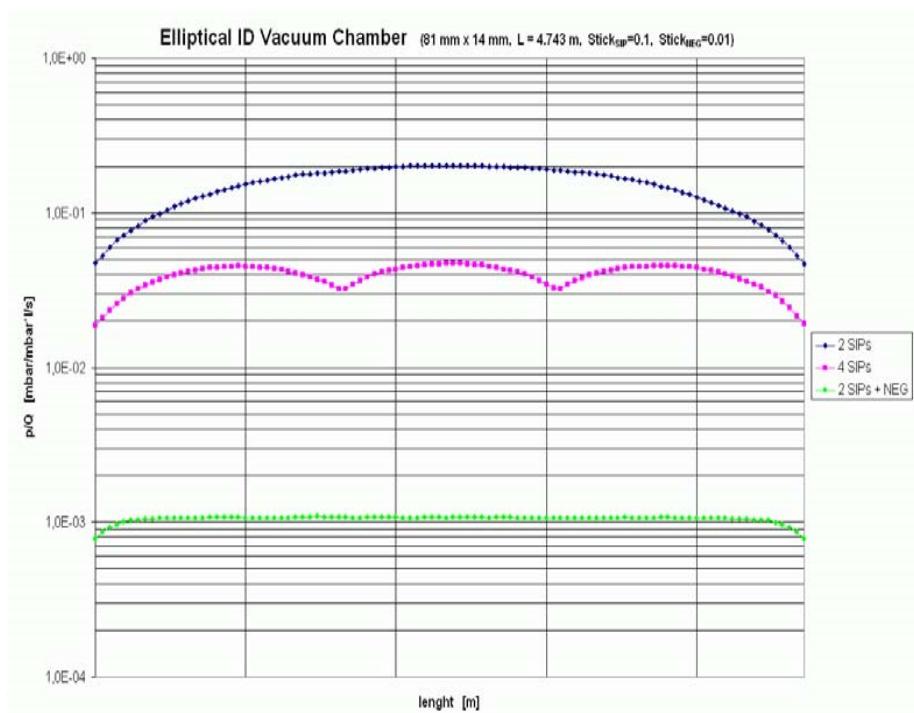
**Titane Zirconium Vanadium coating**

**Electron and photon stimulated desorption photons (ESD and PSD) are reduced**



P. Chiggiato, R. Kersevan / Vacuum 60 (2001) 67-72

**A low secondary electron yield (SEY)**

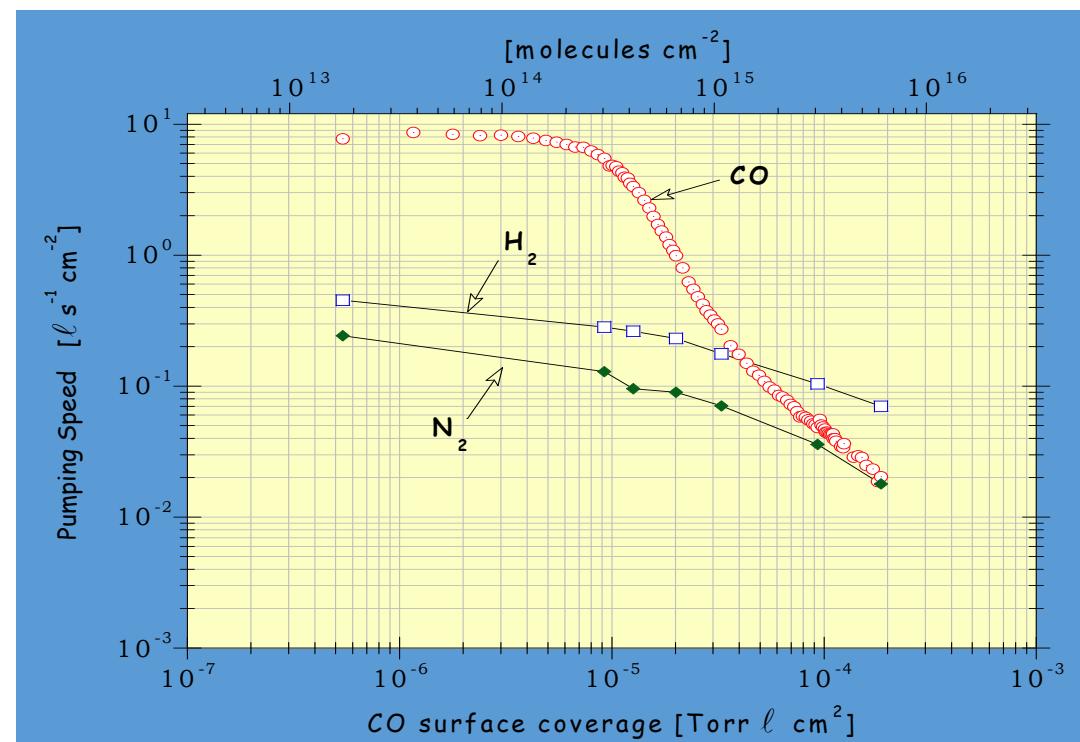


# NEG coating-vacuum disadvantage

Titane Zirconium Vanadium coating

**Selective pumping speed**  
(No pumping of rare gas, CH<sub>4</sub>)

**saturation effect**



P. Chiggiato, R. Kersevan / Vacuum 60 (2001) 67-72

# Conclusion

**Trend:** High luminosity accelerators (involves small-sized beams, high current and a high repetition frequency).

Many beams interactions, residual gas and surface will generate induced outgassing sources and impact the shape and the beam energy

Reduction of induced outgassing sources

Geometry, coating, surface condition, **scrubbing**,.....

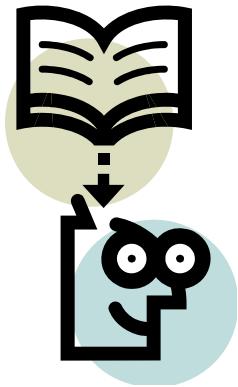
Increase the effective pumping speed

Distributed pumping

NEG strips

Neg coating (TiZrV)



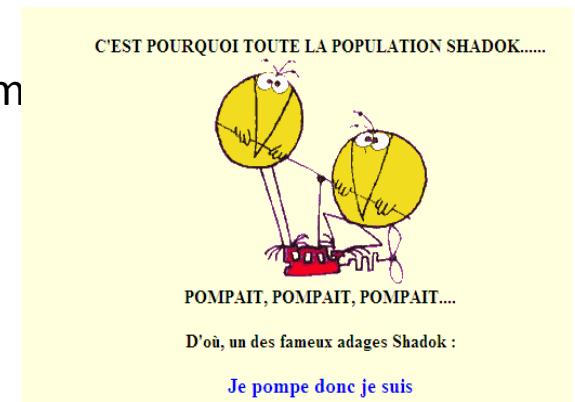


## Some references

- Cern Accelerator School, Vacuum technology, CERN 99-05
- Cern Accelerator School, Vacuum in accelerators, CERN 2007-03
- Scientific foundations of vacuum technique, S. Dushman, J.M Lafferty. J. Wiley & sons. Elsevier Science.
- Vacuum Technology, A. Roth. Elsevier Science.
- Jacow
- L'ultra vide des grands instruments – V. Baglin Gif-sur-Yvette - 22 septembre 2009

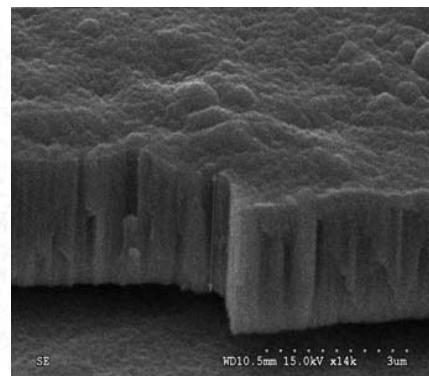
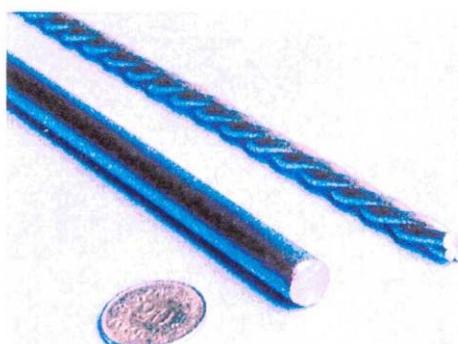
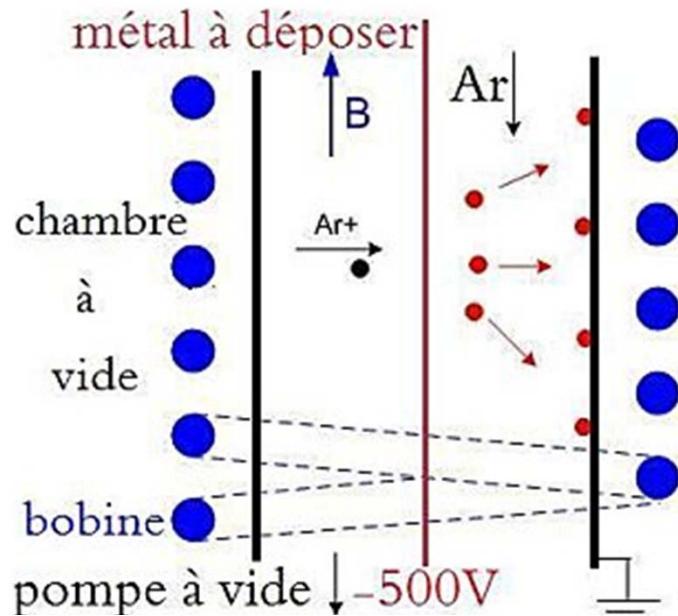
## Journals

- Journal of vacuum science and technology
- Vacuum
- Physical review special topics Accelerators and Beam



# Le dépôt NEG

## La pulvérisation cathodique magnétron



### Paramètres de dépôt

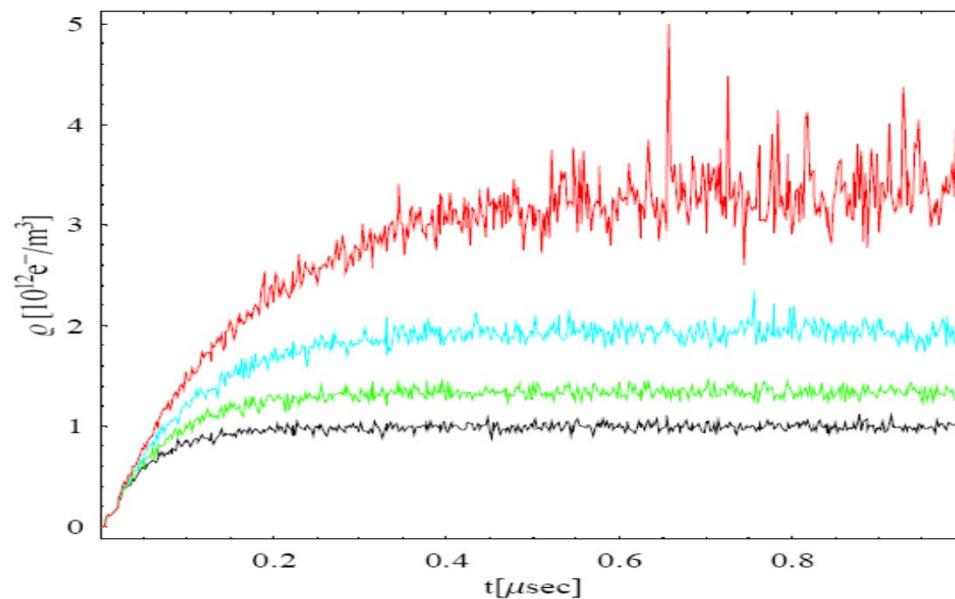
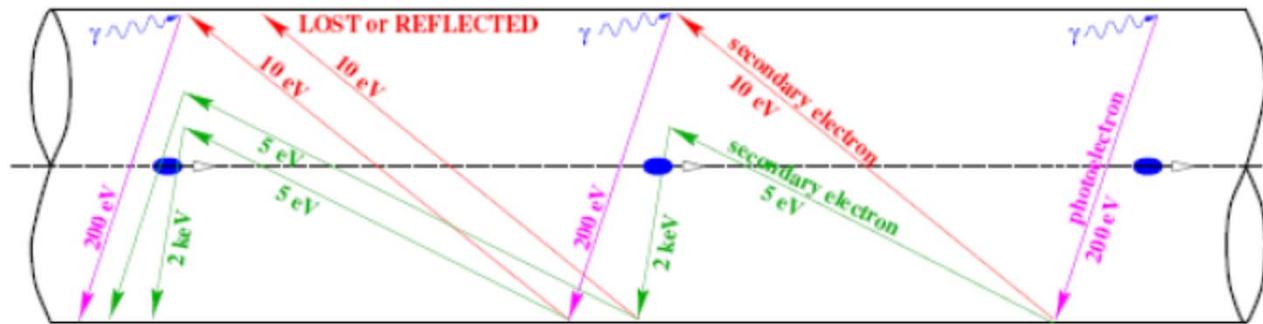
**B = 100 G**

**V = - 500 V**

**Pression Krypton :  $2 \cdot 10^{-2}$  mbar**

**Vitesse de dépôt : 1 Å/s**

# Electron Cloud Effects



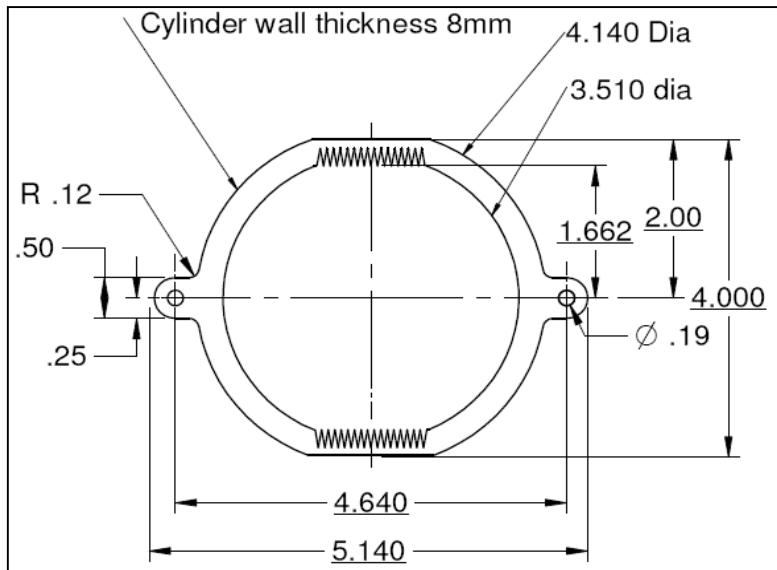
95% prot.

$\delta_{max}=1$

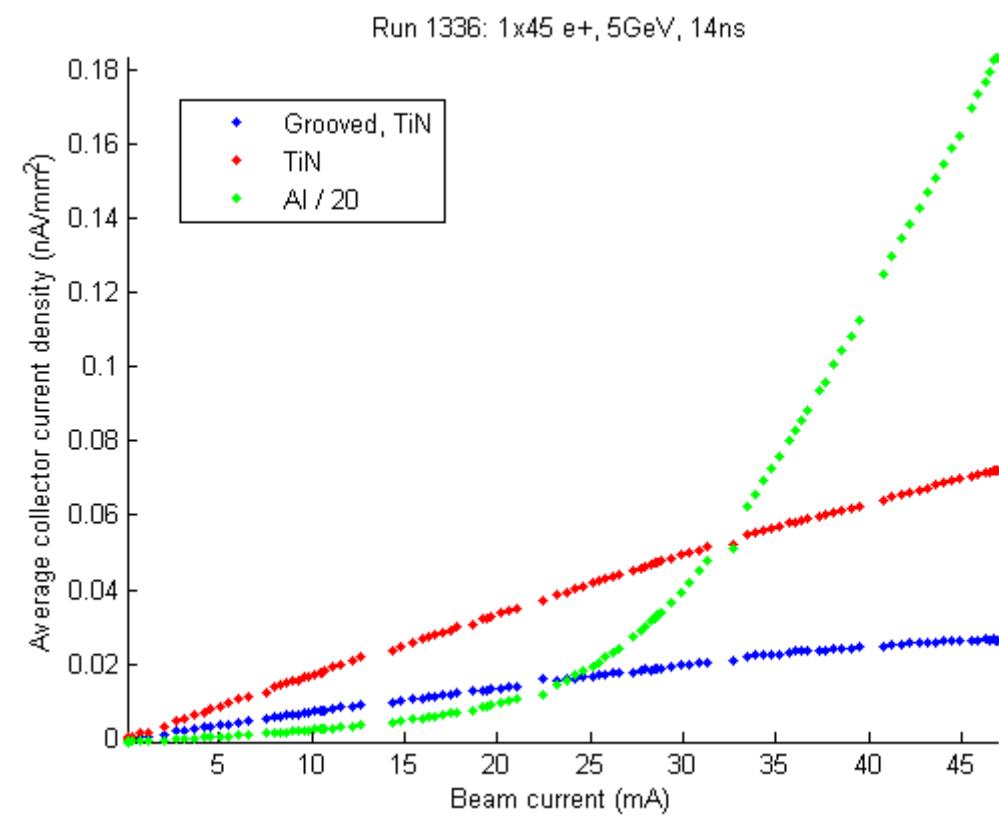
$\delta_{max}=1.1$

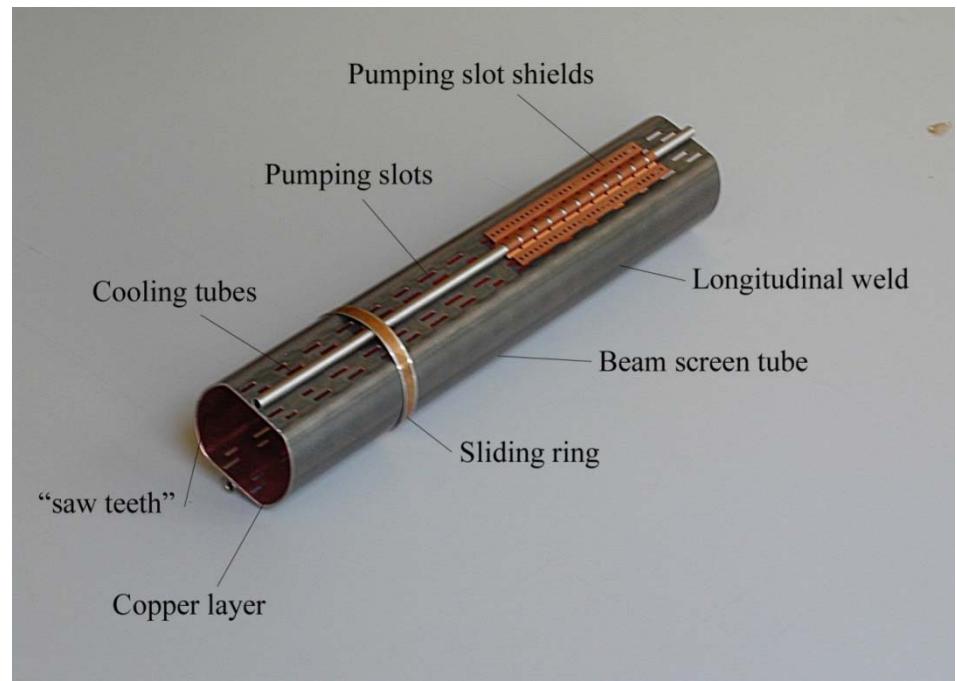
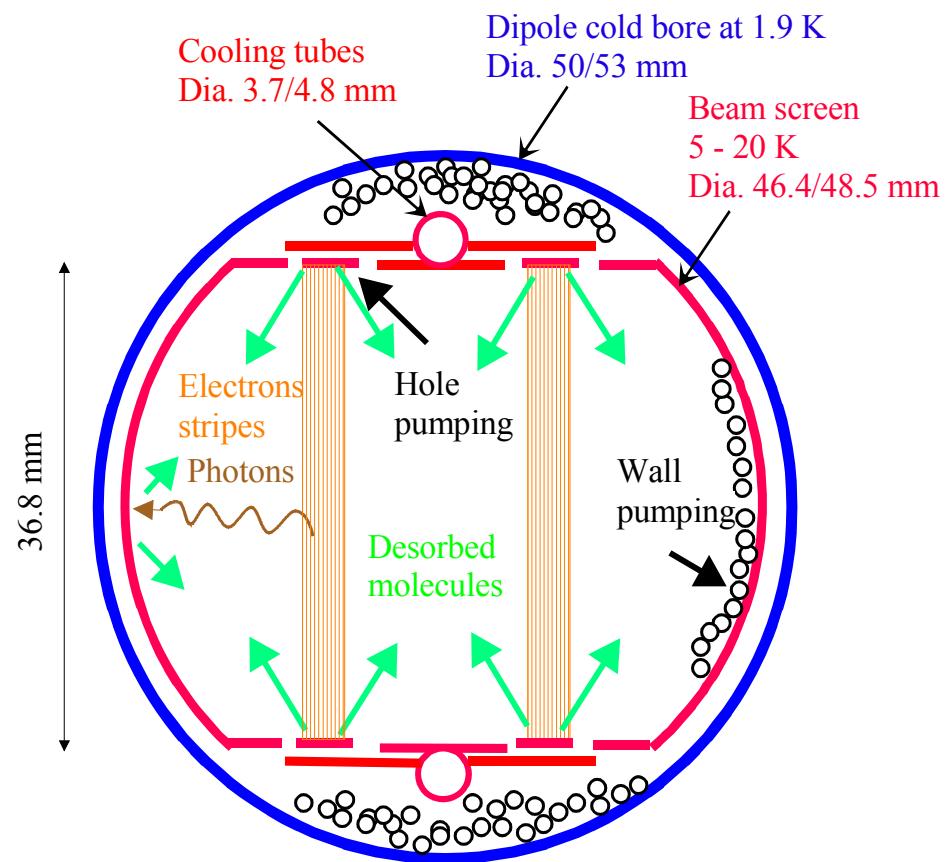
$\delta_{max}=1.2$

$\delta_{max}=1.3$



M. Pivi and L. Wang design, SLAC





# POMPES IONIQUES

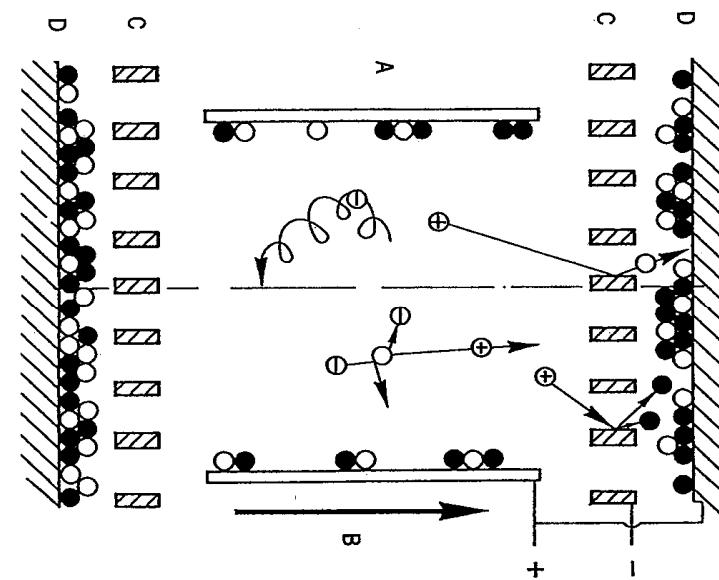
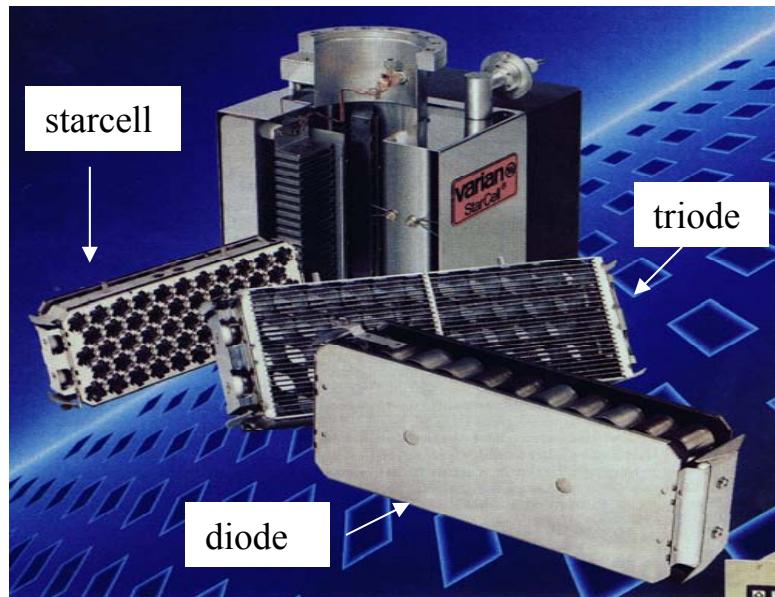
Trois phénomènes de pompage :

- par chimisorption → effet Getter (gaz actifs, CO, CO<sub>2</sub>, H<sub>2</sub>, N<sub>2</sub>, O<sub>2</sub>,...)
- par diffusion ( principalement H<sub>2</sub>)
- par physisorption → enterrement (unique pompage pour les gaz rares)

Principalement deux configurations:

- Pompes ioniques Diodes (et noble diode)
- Pompes ioniques triodes (et starcell)

- Atomes de titane
- Particules gazeuses
- ⊕ ions
- ⊖ électrons

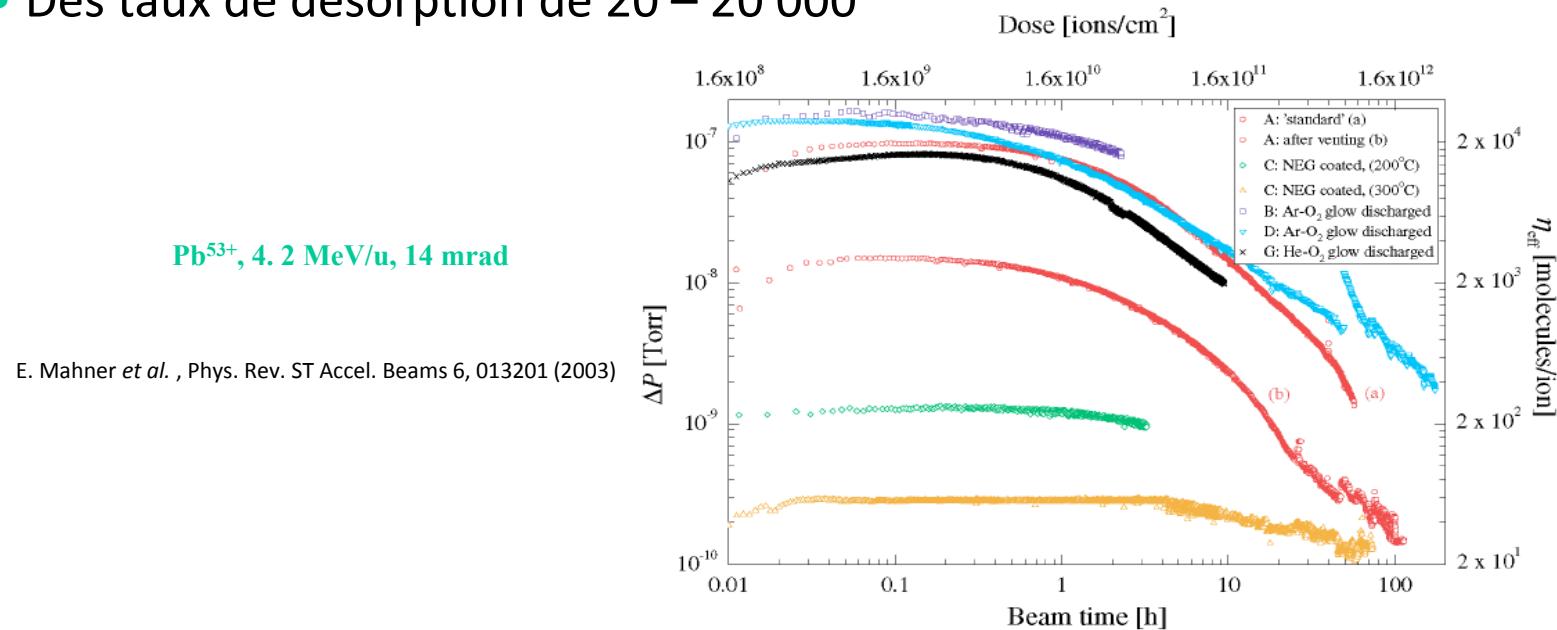


Pompe ionique triode

Ecole Doctorale Phenics

# Ions à très haute énergie

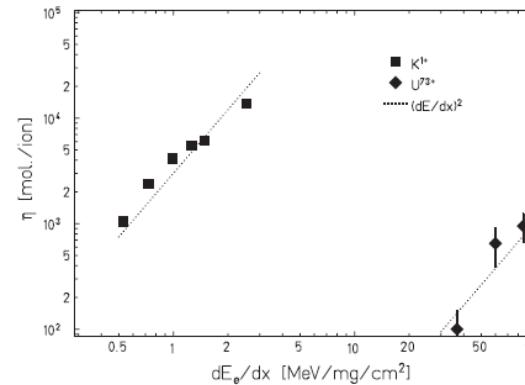
- Des taux de désorption de 20 – 20 000



- La désorption est déterminée par l'énergie donnée aux électrons (pouvoir d'arrêt électronique)

$$\eta_{\text{ion}} \propto \left( \frac{dE_e}{dx} \right)^2$$

L. Prost et al., PRL 98, 064801 (2007)



- La désorption induite par les électrons est le mécanisme responsable

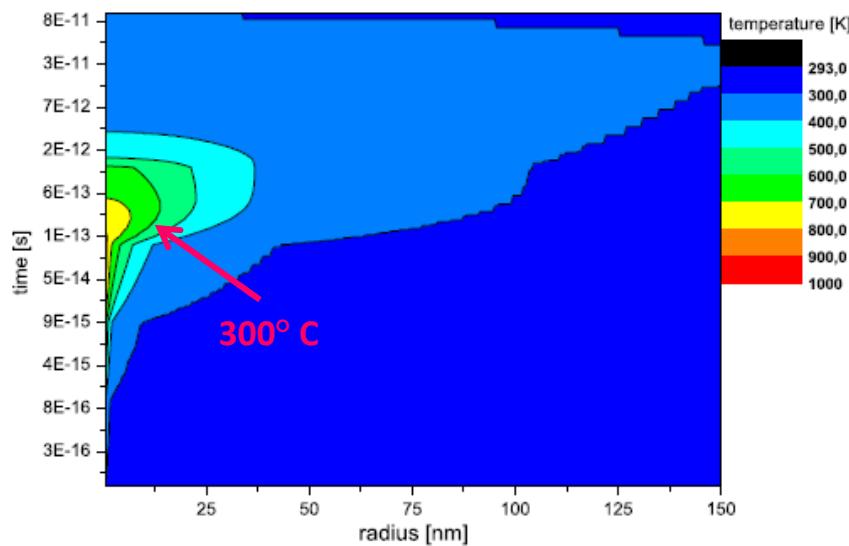
# Mécanisme

- Effet de surface (sauf diffusion H<sub>2</sub>) dû à une activation thermique
- « Inelastic thermal spike model » : carte de température couplée au modèle de désorption thermique

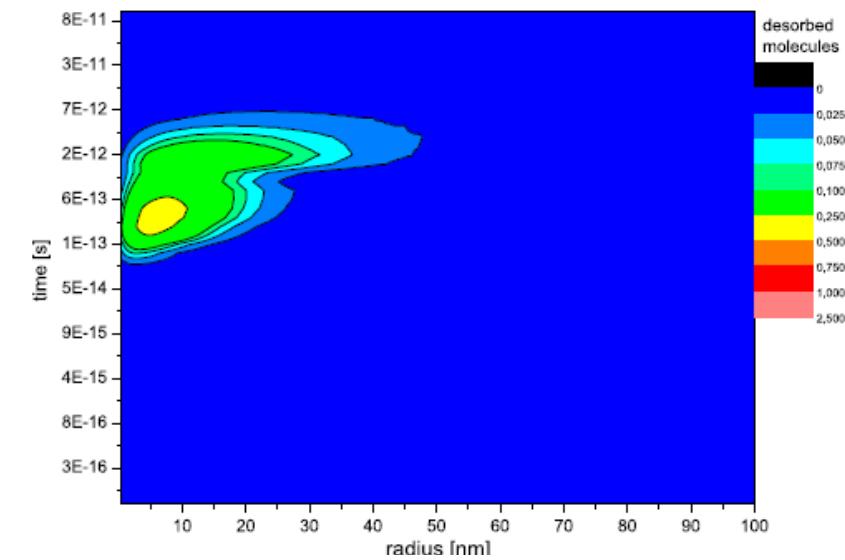
$$\eta = \int_0^{t_{\max}} \int_0^{r_{\max}} v_0(T(r,t)) \cdot \tilde{n}(r,t) \cdot \exp\left(-\frac{E_{\text{des}}}{k_B \cdot T(r,t)}\right) \cdot 2\pi \cdot r dr dt,$$

M. Bender et al., NIM B 267 (2007) 885-890

Xe<sup>29+</sup>, 1.4 MeV/u, Perpendiculaire



Temperature of atomic Cu subsystem after Xe impact



Desorbed particles per Xe per dt

$$\eta_{\text{calculated}} = 185$$

# Remèdes

- Utilisation de revêtements NEG (LEIR, RHIC, GSI)
- Intercepter les ions « perdus » sur des collimateurs dédiés :
  - LEIR : plaquage d'or de 30 µm sur de l'acier 316 LN, incidence perpendiculaire
  - GSI : plaquage d'or de 0.1 µm, incidence perpendiculaire. Absorbeur introduit dans une chambre secondaire. Revêtement NEG
- Utiliser le conditionnement par le faisceau

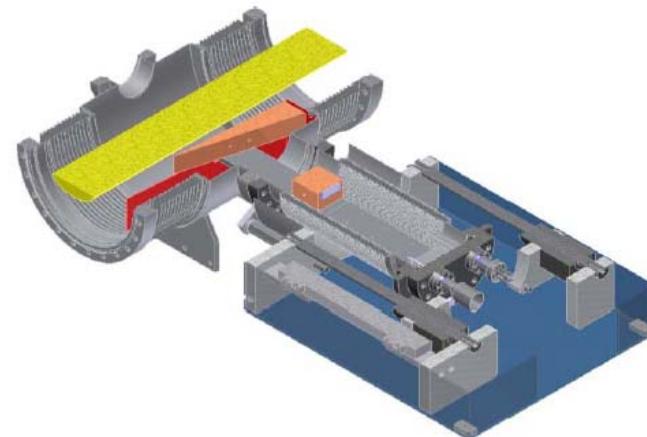
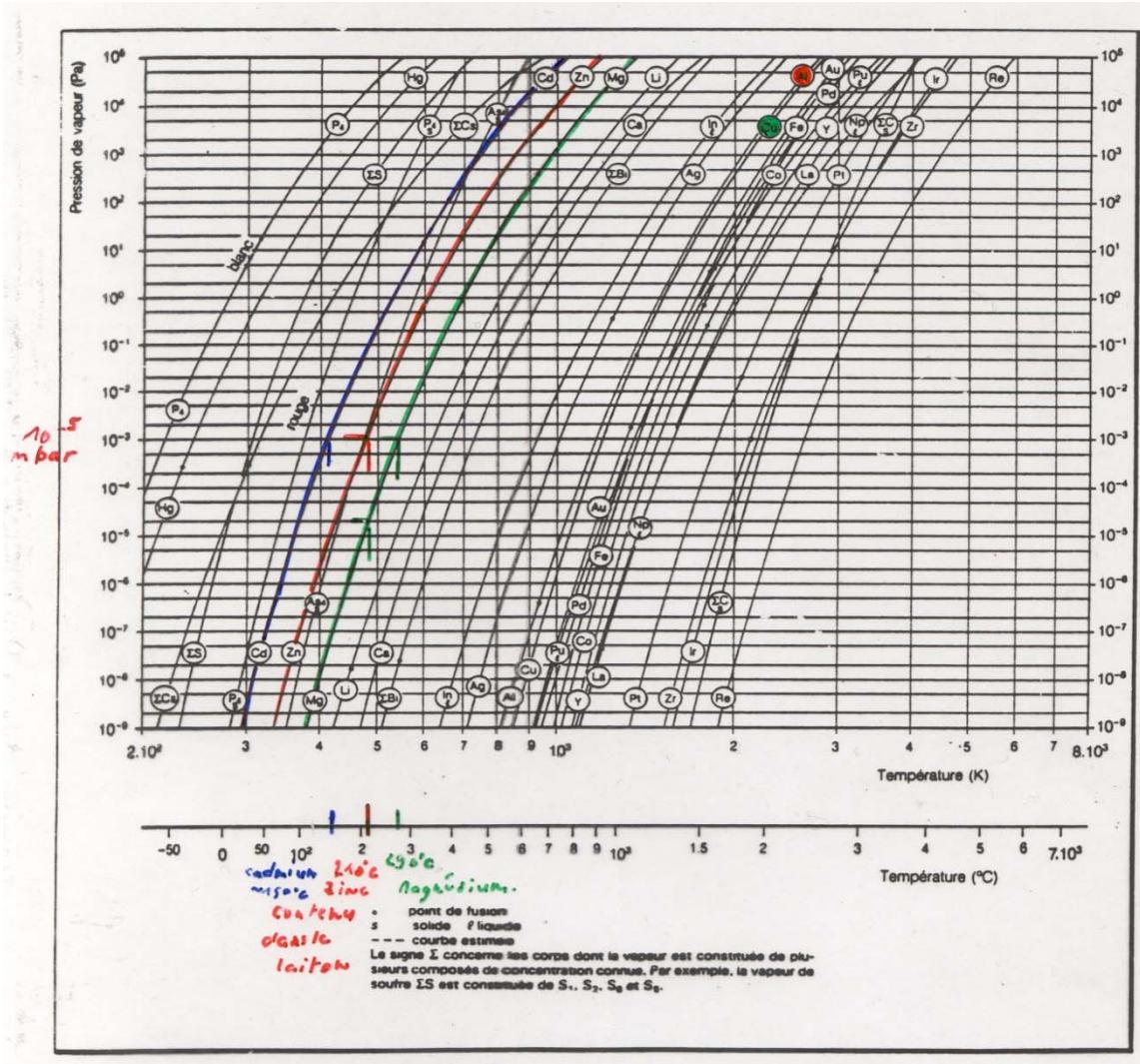


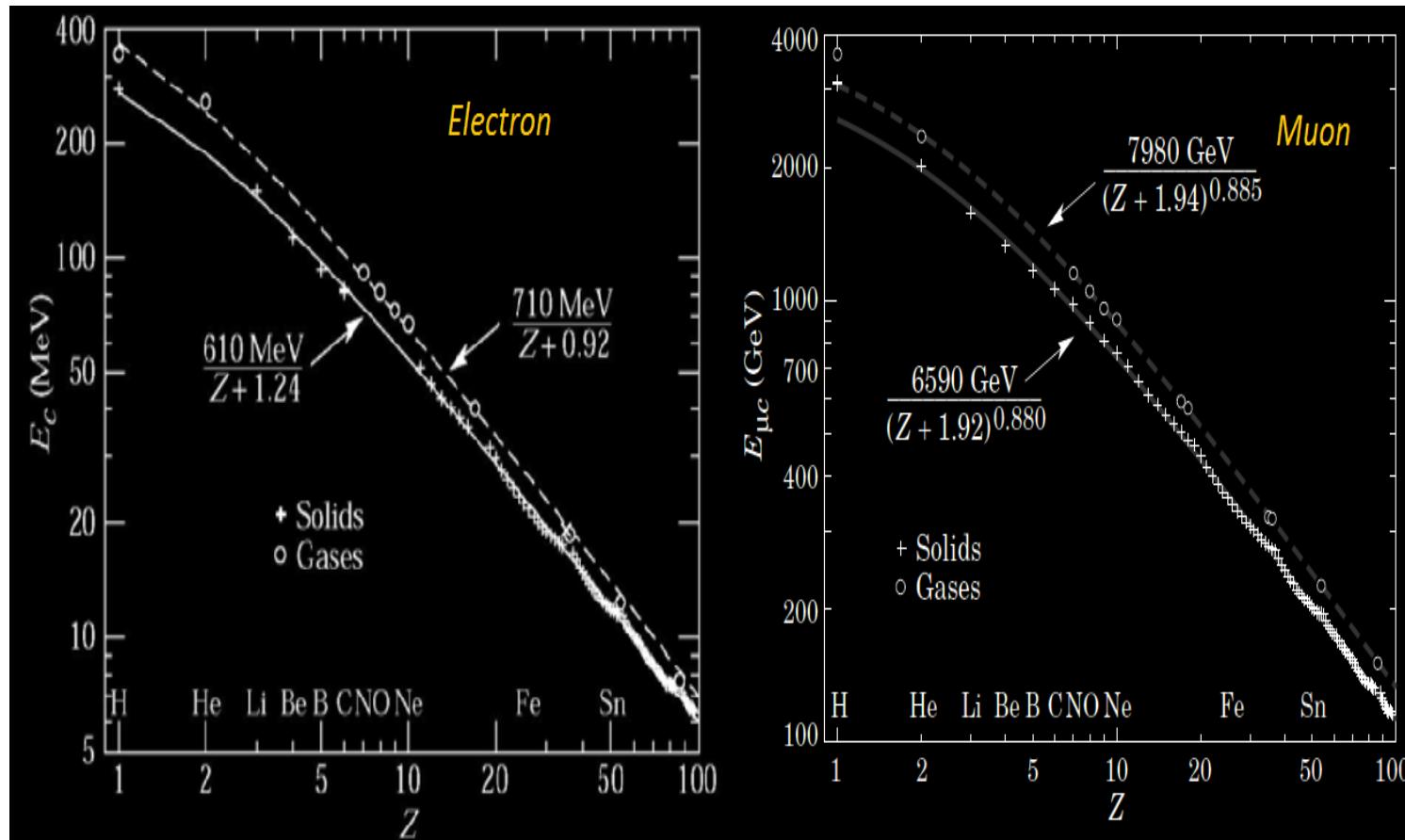
Figure 2: Horizontal cut through the installed SIS18 ion catcher prototype. Yellow: beam, red: secondary chamber, brown: beam absorbers.

C. Omet *et. al.* EPAC 2008, Genoa, Italy

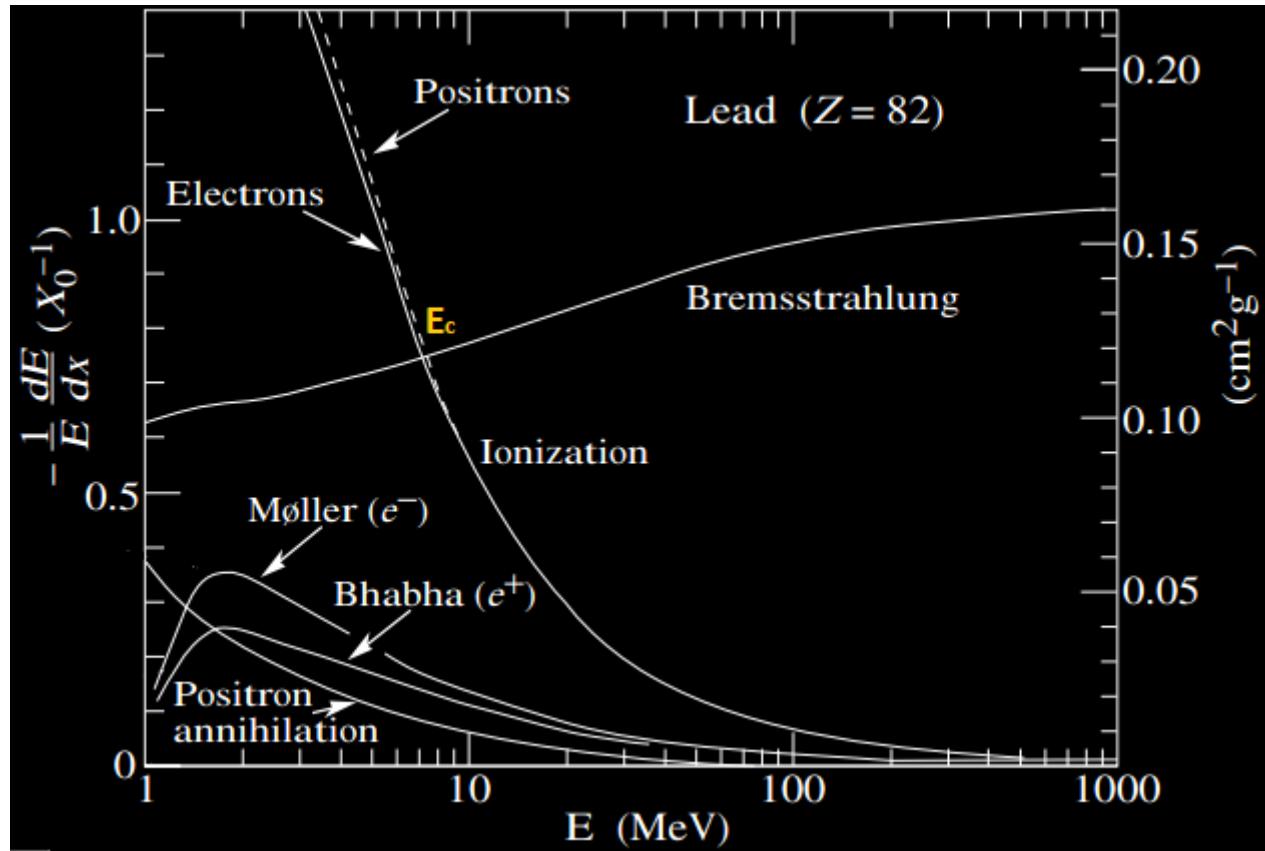
# Vapor pressure



## Energie critique ‘collision élastique/ émission radiative) en fonction de Z



Perte d'énergie des électrons dans du plomb par unité de radiation X0.  
 L'énergie critique est de [7,43 MeV](#).



Plomb 11,35 g/cm<sup>3</sup> (20°C)